



Datasheet

# Ultra-low-power wireless 32-bit MCUs Arm<sup>®</sup>-based Cortex<sup>®</sup>-M0+ with Bluetooth<sup>®</sup> LE and 2.4 GHz radio solution







# Product status STM32WB06xC STM32WB06CC STM32WB06KC STM32WB07CC STM32WB07XC STM32WB07KC

#### **Features**

#### Includes ST state-of-the-art patented technology.

#### Bluetooth® LE

- LE 2M
- LE coded
- Extended advertising
- LE channel classification
- LE data packet length extension
- LE secure connections
- Link layer privacy
- Periodic advertising
- Periodic advertising with responses
- Advertising coding selection
- · Encrypted advertising data
- LE L2CAP connection-oriented channel
- LE power control
- Enhanced attribute protocol
- Connection subrating
- · Isochronous channels
- Qualified against Bluetooth<sup>®</sup> core 5.4

#### Radio

- Rx sensitivity level: -97 dBm @ 1 Mbps, -104 dBm @ 125 kbps (long range)
- Programmable output power up to +8 dBm (at antenna connector)
- Data rate supported: 2 Mbps, 1 Mbps, 500 kbps, and 125 kbps
- 128 physical connections
- Integrated balun
- Support for external PA
- STM32WB0xxC core coprocessor (DMA based) for Bluetooth<sup>®</sup> LE timing critical operation
- 2.4 GHz proprietary radio driver
- Suitable for systems requiring compliance with the following radio frequency regulations: ETSI EN 300 328, EN 300 440, FCC CFR47 part 15, ARIB STD-T66
- Available integrated passive device (IPD) companion chip for optimized matching and filtering

#### Ultra-low-power features (ultra-low-power devices)

- 10 nA in Shutdown mode (1.8 V)
- 0.6  $\mu A$  in Deepstop mode (with external LSE and Bluetooth® LE wake-up sources, 1.8 V)
- 0.9 μA in Deepstop mode (with internal LSI and Bluetooth<sup>®</sup> LE wake-up sources, 1.8 V)



- 4.3 mA peak current in Tx (@ 0 dBm, 3.3 V)
- 3.4 mA peak current in Rx (@ sensitivity level, 3.3 V)
- High performance and ultralow power Arm<sup>®</sup> Cortex<sup>®</sup>-M0+ 32-bit, running up to 64 MHz
- Dynamic current consumption: 16.5 μA/MHz
- Operating supply voltage: from 1.7 to 3.6 V

#### **Security**

- Flash read/write protection
- SWD disabling
- Secure bootloader
- True random number generator (RNG)
- Hardware encryption AES maximum 128-bit security coprocessor
- Hardware public key accelerator (PKA)
- CRC calculation unit
- 64-bit unique ID

#### **Clock management**

- High-efficiency embedded SMPS step-down converter with intelligent bypass mode
- Ultra-low-power power-on-reset (POR) and power-down-reset (PDR)
- Programmable voltage detector (PVD)
- Fail-safe 32 MHz crystal oscillator with integrated trimming capacitors
- 32 kHz crystal oscillator
- Internal low-power 32 kHz RO

#### **Memories**

- On-chip nonvolatile flash memory of 256 Kbytes
- On-chip RAM of 64 Kbytes or 32 Kbytes
- One-time-programmable (OTP) memory area of 1 Kbyte
- Embedded UART bootloader
- Ultra-low-power modes with or without timer and RAM retention

#### Security

- Flash read/write protection
- SWD disabling
- Secure bootloader
- True random number generator (RNG)
- Hardware encryption AES maximum 128-bit security coprocessor
- Hardware public key accelerator (PKA)
- CRC calculation unit
- 64-bit unique ID

#### System peripherals

- 1x DMA controller with eight channels supporting ADC, SPI, I2C, USART, and LPUART
- 1x SPI
- 2x SPI/I2S
- 2x I2C (SMBus/PMBus)
- 1x PDM (digital microphone interface)
- 1x LPUART
- 1x USART (ISO 7816 smartcard mode, IrDA, SPI controller, and modbus)

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- 1x independent WDG
- 1x real-time clock (RTC)
- 1x independent SysTick
- 1x 16-bit, six channel advanced timer

#### General-purpose inputs/outputs

- Quadrature decoder
- Up to 32 fast I/Os
- 28 of them with wake-up capability
- 31 of them 5 V tolerant

#### **Analog peripherals**

- 12-bit ADC with eight input channels, up to 16 bits with a decimation filter
- · Battery monitoring
- Analog watchdog
- Analog mic I/F with PGA

#### **Debug**

- Development support
- Serial wire debug (SWD)
- · Four breakpoints and two watchpoints

All packages are ECOPACK2 compliant.

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#### 1 Introduction

This document provides information on STM32WB0xxC devices, such as description, functional overview, pin assignment and definition, electrical characteristics, packaging and ordering information.

It must be read in conjunction with the STM32WB0xxC reference manual (RM0530).

For information on the device errata with respect to the datasheet and reference manual, refer to the STM32WB0xxC errata sheet (ES0632).

For information on the Arm<sup>®</sup> Cortex<sup>®</sup>-M0+ core, refer to the *Arm*<sup>®</sup> *Cortex*<sup>®</sup>-*M0+ Processor Technical Reference Manual*, available from the www.arm.com website.

For information on Bluetooth®, refer to http://www.bluetooth.com website.

Note: Arm is a registered trademark of Arm Limited (or its subsidiaries) in the US and/or elsewhere.



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#### 2 Description

The STM32WB0xxC is an ultra-low-power programmable Bluetooth<sup>®</sup> LE wireless SoC solution. It embeds STMicroelectronics state-of-art 2.4 GHz RF radio IPs combining unparalleled performance with extremely long-battery lifetime. It is compliant with Bluetooth<sup>®</sup> LE addressing point-to-point connectivity and Bluetooth<sup>®</sup> Mesh networking and allows large-scale device networks to be established in a reliable way. The STM32WB0xxC is also suitable for 2.4 GHz proprietary radio wireless communication to address ultra-low latency applications.

The STM32WB0xxC embeds a Cortex<sup>®</sup>-M0+ microcontroller that can operate up to 64 MHz and also the BlueNRG core coprocessor (DMA based) for Bluetooth<sup>®</sup> LE timing critical operations.

In addition, the STM32WB0xxC provides enhanced security hardware support by dedicated hardware functions:

True random number generator (RNG), encryption AES maximum 128-bit security coprocessor, public key accelerator (PKA), CRC calculation unit, 64-bit unique ID, flash memory read and write protection.

The STM32WB0xxC can be configured to support standalone or network processor applications. In the first configuration, the STM32WB0xxC operates as a single device in the application for managing both the application code and the Bluetooth® LE stack.

The STM32WB0xxC embeds high-speed and flexible memory types: flash memory of 256 Kbytes, RAM memory of 64 Kbytes, one-time-programmable (OTP) memory area of 1 Kbyte, ROM memory of 7 Kbytes (ST reserved area).

Direct data transfer between memory and peripherals and from memory-to-memory is supported by eight DMA channels with a full flexible channel mapping by the DMAMUX peripheral.

The STM32WB0xxC embeds a 12-bit ADC, allowing measurements of up to eight external sources and up to three internal sources, including battery monitoring and a temperature sensor.

The STM32WB0xxC has a low-power RTC and one advanced 16-bit timer.

The STM32WB0xxC features standard and advanced communication interfaces:

1x SPI, 2x SPI/I2S, 1x LPUART, 1x USART supporting ISO 7816 (smartcard mode), IrDA, and modbus mode, 2x I<sup>2</sup>C supporting SMBus/PMBus, 1x channel PDM.

The STM32WB0xxC operates in the -40 to +105°C temperature range from a 1.7 V to 3.6 V power supply. A comprehensive set of power-saving modes enables the design of low-power applications.

The STM32WB0xxC integrates a high efficiency SMPS step-down converter and an integrated PDR circuitry with a fixed threshold that generates a device reset when the  $V_{DD}$  drops under 1.65 V.

The STM32WB0xxC comes in different package versions supporting up to:

32 I/Os for the VFQFPN48 package, 20 I/Os for the VFQFPN32 package, 30 I/Os for the WLCSP49 package.

Refer to Table 1 for the list of peripherals available on each part number.

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Table 1. Device features and peripheral counts

| Peripherals                |                                           | STM32WB06KC                                                           | STM32WB06CC             | STM32WB07KC              | STM32WB07CC |  |  |
|----------------------------|-------------------------------------------|-----------------------------------------------------------------------|-------------------------|--------------------------|-------------|--|--|
| Flash memory (Kbytes)      |                                           |                                                                       | 256 Kbytes              |                          |             |  |  |
|                            | SRAM0                                     | 16 K                                                                  | oytes                   | 16 K                     | bytes       |  |  |
| ODAM (ICh. 4)              | SRAM1                                     | 16 K                                                                  | oytes                   | 16 K                     | bytes       |  |  |
| SRAM (Kbytes)              | SRAM2                                     |                                                                       | -                       | 16 K                     | bytes       |  |  |
|                            | SRAM3                                     |                                                                       | -                       | 16 K                     | bytes       |  |  |
| Bluetooth® LE              |                                           |                                                                       | Yes                     |                          |             |  |  |
|                            | General purpose                           |                                                                       | 1 x 16-bit, 6 chanr     | nel advanced timer       |             |  |  |
| Timers                     | 2.4 GHz proprietary radio timer low-power | 32-bit                                                                |                         |                          |             |  |  |
| SysTick                    |                                           |                                                                       |                         | 1                        |             |  |  |
| Real-time clock (RTC)      |                                           |                                                                       | Y                       | es                       |             |  |  |
| Random number generato     | r                                         | Yes                                                                   |                         |                          |             |  |  |
| AES                        |                                           | Yes                                                                   |                         |                          |             |  |  |
| Public key accelerator (PK | A)                                        | Yes                                                                   |                         |                          |             |  |  |
|                            | SPI/I2S                                   | 2 with I2S feature                                                    |                         |                          |             |  |  |
| Communication interfaces   | I2C                                       | 1                                                                     |                         |                          |             |  |  |
| Communication interfaces   | USART                                     | 1                                                                     |                         |                          |             |  |  |
|                            | LPUART                                    | 1                                                                     |                         |                          |             |  |  |
| 12-bit ADC with 1 PDM      | Number of channels                        |                                                                       | {                       | 8                        |             |  |  |
| GPIOs                      |                                           | 32                                                                    |                         |                          |             |  |  |
| Wakeup pins                |                                           | 28                                                                    |                         |                          |             |  |  |
| Maximum CPU frequency      | (MHz)                                     | 64                                                                    |                         |                          |             |  |  |
| Operating voltage          |                                           | 1.7 to 3.6 V                                                          |                         |                          |             |  |  |
| Operating temperature      |                                           |                                                                       | Temperature rang        | ge: −40 to 105 °C        |             |  |  |
|                            |                                           |                                                                       | VFQF                    | PN32                     |             |  |  |
|                            |                                           | 5 x 5 mm, 0.50 mm pitch, very fine pitch quad flat no lead package    |                         |                          |             |  |  |
| Packages                   |                                           | VFQFPN48                                                              |                         |                          |             |  |  |
| 3-3-3                      |                                           | 6 x 6 mm                                                              | 0.40 mm pitch, very fin | e pitch quad flat no lea | d package   |  |  |
|                            |                                           | WLCSP49                                                               |                         |                          |             |  |  |
|                            |                                           | 3.140 x 3.140 mm, 0.40 mm pitch, wafer level chip scale array package |                         |                          |             |  |  |

Figure 1 shows the general block diagram of the device family.

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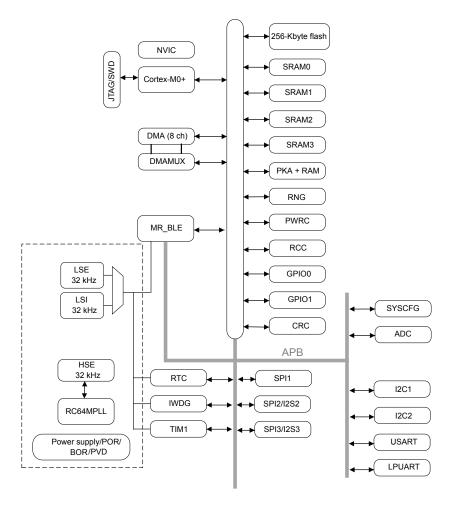


Figure 1. STM32WB0xxC block diagram

DT58101V1



#### 3 Functional overview

#### 3.1 ARM Cortex–M0+ core with MPU

The STM32WB0xxC contains an ARM Cortex-M0+ microcontroller core. The Cortex-M0+ was developed to provide a low-cost platform that meets the needs of CPU implementation, with a reduced pin count and low-power consumption, while delivering outstanding computational performance and an advanced response to interrupts. The Cortex-M0+ can run from 1 MHz up to 64 MHz.

The Cortex-M0+ processor is built on a highly area and power optimized 32-bit processor core, with a 2-stage pipeline Von Neumann architecture. The processor delivers exceptional energy efficiency through a small but powerful instruction set and extensively optimized design, providing high-end processing hardware including a single-cycle multiplier.

The interrupts are handled by the Cortex-M0+ Nested Vector Interrupt Controller (NVIC). The NVIC controls specific Cortex-M0+ interrupts as well as the STM32WB0xxC peripheral interrupts. With its embedded ARM core, the STM32WB0xxC family is compatible with all ARM tools and software.

#### 3.2 Memory protection unit (MPU)

The MPU is used to manage accesses to memory to prevent one task from accidentally corrupting the memory or resources used by any other active task. This memory area is organized into up to 8 protected areas. The protection area sizes are between 32 bytes and the whole 4 gigabytes of addressable memory.

The MPU is especially helpful for applications where some critical or certified code has to be protected against the misbehavior of other tasks. It is usually managed by an RTOS (real-time operating system). If a program accesses a memory location that is prohibited by the MPU, the RTOS can detect it and take action. In an RTOS environment, the kernel can dynamically update the MPU area settings, based on the process to be executed.

The MPU is optional and can be bypassed for applications that do not need it.

#### 3.3 Memories

#### 3.3.1 Embedded flash memory

The flash memory controller implements the erase and program Flash memory operation. The flash controller also implements the read and write protection.

The flash memory features are:

- Memory organization:
  - 1 bank of 256 KB
  - Page size: 2 KB
  - Page number 128
- 32-bit wide data read/write
- Page erase and mass erase

The flash memory controller features are:

- Flash memory read operations
- Flash memory write operations: single data write or 4 x 32-bits burst write
- Flash memory erase operations
- Page write protect mechanism

#### 3.3.2 Embedded SRAM

The STM32WB0xxC has a total of 64 KB of embedded SRAM, split into four banks as shown in the following table:

Table 2. SRAM overview

| SRAM bank | Size  | Address     | Retained in Deepstop |
|-----------|-------|-------------|----------------------|
| SRAM0     | 16 KB | 0x2000 0000 | Always               |

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| SRAM bank | Size  | Address     | Retained in Deepstop     |
|-----------|-------|-------------|--------------------------|
| SRAM1     | 16 KB | 0x2000 4000 | Programmable by the user |
| SRAM2     | 16 KB | 0x2000 8000 | Programmable by the user |
| SRAM3     | 16 KB | 0x2000 C000 | Programmable by the user |

#### 3.3.3 Embedded ROM

The STM32WB0xxC has a total of 7 Kbytes of embedded ROM. This area is ST reserved and contains:

- The UART bootloader from which the CPU boots after each reset (first 6 Kbytes of ROM memory)
- Some ST reserved values including the ADC trimming values (the last 1 Kbyte of ROM memory)

#### 3.3.4 Embedded OTP

The one-time-programmable (OTP) is a memory of 1 Kbyte dedicated for user data. The OTP data cannot be erased.

The user can protect the OTP data area by writing the last word at address 0x1000 1BFC and by performing a system reset. This operation freezes the OTP memory from further unwanted write operations.

#### 3.4 Security and safety

The STM32WB0xxC contains many security blocks for the Bluetooth® LE and the host application. It includes:

- Flash read/write protections
- As protection against potential hacker attacks, the SWD access can be disabled
- Secure bootloader
- Customer storage of the Bluetooth<sup>®</sup> LE keys
- True random number generator (RNG)
- Private key accelerator (PKA) including:
  - Elliptic curve Diffie-Hellman (ECDH) public-private key pair calculation accelerator
  - Based on the Montgomery method for fast modular multiplications
  - Built-in Montgomery domain inward and outward transformations
    - AMBA® AHB lite target interface with a reduced command set
- Cyclic redundancy check calculation unit (CRC)

#### 3.5 Boot modes

After the CPU boots, the application software has the capability to modify the memory map at address 0x0000 0000. This modification is carried out by programming the REMAP bit in the flash memory controller.

The following memory can be remapped:

- · Main flash memory
- SRAM0 memory

#### 3.6 Radio system

#### 3.6.1 RF subsystem

The STM32WB0xxC embeds an ultralow power radio, compliant with the Bluetooth<sup>®</sup> LE specification. The Bluetooth<sup>®</sup> LE features 1 Mbps and 2 Mbps transfer rates as well as long range options (125 kbps, 500 kbps), supports multiple roles simultaneously acting at the same time as a Bluetooth<sup>®</sup> LE sensor and a hub device.

The Bluetooth® LE protocol stack is implemented by an efficient system partitioned as follows:

- Hardware part: BlueCore handling time-critical and time consuming Bluetooth<sup>®</sup> LE protocol parts
- Firmware part: Arm<sup>®</sup> Cortex<sup>®</sup>-M0+ core handling nontime critical Bluetooth<sup>®</sup> LE protocol parts

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#### 3.6.1.1 RF front-end block diagram

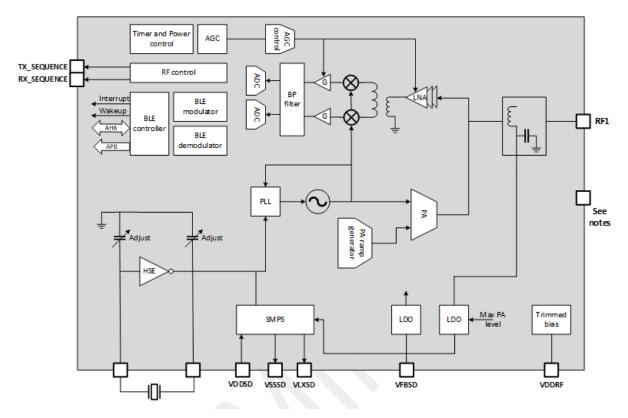
The RF front-end is based on a direct modulation of the carrier in Tx, and uses a low IF architecture in Rx mode.

Thanks to an internal transformer with RF pins, the circuit directly interfaces the antenna (single ended connection, impedance close to 50  $\Omega$ ). The natural band pass behavior of the internal transformer simplifies outside circuitry aimed at harmonic filtering and out of band interferer rejection.

In transmit mode, the maximum output power is user selectable through the programmable LDO voltage of the power amplifier. A linearized, smoothed analog control offers a clean power ramp-up.

In receive mode, the automatic gain control (AGC) can reduce the gain in both the RF and IF stages, optimizing interferer rejection. Thanks to the use of complex filtering and a highly accurate I/Q architecture, high sensitivity, and excellent linearity can be achieved.

Figure 2. STM32WB0xxC RF block diagram



Note:

VFQFPN32 and VFQFPN48: VSS through exposed pad, and VSSRF pins must be connected to ground plane. WLCSP49: VssRF pins must be connected to ground plane.

#### 3.6.1.2 IPDs for STM32WB06xC and STM32WB07xC

Table 3 lists the available IPD variants for the STM32WB06xC and STM32WB07xC devices.

Table 3. IPDs for STM32WB0xxC

| IPD           | MCU package           | STM32WB06xC and STM32WB07xC part number                  |
|---------------|-----------------------|----------------------------------------------------------|
| MLPF-NRG-01D3 | VFQFPN32,<br>VFQFPN48 | STM32WB06KCV, STM32WB06CCV<br>STM32WB07KCV, STM32WB07CCV |
|               | WLCSP49               | STM32WB06CCF, STM32WB07CCF                               |

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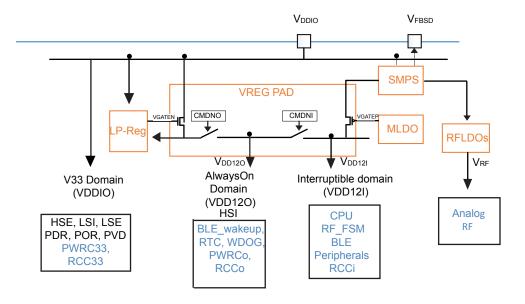
#### 3.7 Power supply management

#### 3.7.1 Power supply schemes

The STM32WB0xxC embeds three power domains:

- VDD33 (VDDIO or VDD):
  - the voltage range is between 1.7 V and 3.6 V
  - it supplies a part of the I/O ring, the embedded regulators and the system analog IPs as power management block and embedded oscillators
- VDD12o:
  - always-on digital power domain
  - this domain is generally supplied at 1.2 V during active phase of the device
  - this domain is supplied at 1.0 V during low power mode (Deepstop)
- VDD12i:
  - interruptible digital power domain
  - this domain is generally supplied at 1.2 V during active phase of the device
  - this domain is shut down during low-power mode (Deepstop)

Figure 3. Power supply domain overview



#### 3.7.2 Power supply supervisor

The STM32WB0xxC device embeds several power voltage monitorings:

- Power-on-reset (POR): during the power-on, the device remains in reset mode if V<sub>DDIO</sub> is below a V<sub>POR</sub> threshold (typically 1.65 V)
- Power-down-reset (PDR): during power-down, the PDR puts the device under reset when the supply voltage (V<sub>DD</sub>) drops below the VPDR threshold (around 20 mV below V<sub>POR</sub>). The PDR feature is always enabled
- Programmable voltage detector (PVD): can be used to monitor the V<sub>DDIO</sub> (against a programmed threshold) or an external analog input signal. When the feature is enabled and the PVD measures a voltage below the comparator, an interrupt is generated (if unmasked)

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#### 3.7.3 SMPS step-down regulator

The device integrates a step-down converter to improve low-power performance when the  $V_{DD}$  voltage is high enough. The SMPS output voltage can be programmed from 1.2 V to 1.90 V. It is internally clocked at 4 MHz or 8 MHz.

The device can be operated without the SMPS by just wiring its output to  $V_{DD}$ . This is the case for applications where the voltage is low, or where the power consumption is not critical.

Except for the configuration SMPS OFF, an L/C BOM must be present on the board and connected to the VFBSD pad.

V<sub>DDSD</sub> V<sub>DDSD</sub> SMPS **SMPS** Step Down Step Down converter converter  $V_{FBSD}$  $V_{FBSD}$ RF  $V_{CAP}$ LDO LDO LDO Reg LDC Reg SMPS supply configuration NOSMPS supply configuration

Figure 4. Power supply configuration

#### 3.7.4 Linear voltage regulators

The digital power supplies are provided by different regulators:

- The main LDO (MLDO):
  - it provides 1.2 V from a 1.4-3.3 V input voltage
  - it supplies both VDD12i and VDD12o when the device is active
  - it is disabled during the low power mode (Deepstop)
- Low power LDO (LPREG):
  - it stays enabled during both active and low power phases
  - it provides 1.0 V voltage
  - it is not connected to the digital domain when the device is active
  - it is connected to the VDD12o domain during low power mode (Deepstop)
- A dedicated LDO (RFLDO) to provide a 1.2 V to the analog RF block

An embedded SMPS step-down converter is available (inserted between the external power and the LDOs).

#### 3.8 Low-power modes

Several operating modes are defined for the STM32WB0xxC:

- Run mode
- Deepstop mode
- Shutdown mode

Table 4. Relationship between the low power modes and functional blocks

| Mode               | Shutdown | Deepstop                     | ldle              | Run               |
|--------------------|----------|------------------------------|-------------------|-------------------|
| CPU                | OFF      | OFF                          | OFF               | ON                |
| Flash              | OFF      | OFF                          | ON                | ON                |
| RAM                | OFF      | ON/OFF granularity 16 Kbytes | ON/OFF            | ON/OFF            |
| Radio              | OFF      | OFF                          | ON/OFF            | ON/OFF            |
| Supply system      | OFF      | OFF                          | ON (DC-DC ON/OFF) | ON (DC-DC ON/OFF) |
| Register retention | OFF      | ON                           | ON                | ON                |

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| Mode              | Shutdown | Deepstop | Idle   | Run    |
|-------------------|----------|----------|--------|--------|
| HS clock          | OFF      | OFF      | ON     | ON     |
| LS clock          | OFF      | ON/OFF   | ON     | ON     |
| Peripherals       | OFF      | OFF      | ON/OFF | ON/OFF |
| Wake-on RTC       | OFF      | ON/OFF   | ON/OFF | NA     |
| Wake-on GPIOs     | OFF      | ON/OFF   | ON/OFF | NA     |
| Wake-on reset pin | ON       | ON       | ON     | NA     |

#### 3.8.1 Run mode

In Run mode the STM32WB0xxC is fully operational:

- All interfaces are active
- · The internal power supplies are active
- The system clock and the bus clock are running
- The CPU core and the radio can be used

The power consumption may be reduced by gating the clock of the unused peripherals.

#### 3.8.2 Deepstop mode

The Deepstop is the only low power mode of the STM32WB0xxC allowing the restart from a saved context environment and the application at wakeup to go on running.

The conditions to enter the Deepstop mode are:

- The radio is sleeping (no radio activity)
- The CPU is sleeping (WFI with SLEEPDEEP bit activated)
- No unmasked wakeup sources are active
- The low power mode selection (LPMS) bit of the power controller unit is 0 (default)

#### In Deepstop mode:

- The system and the bus clocks are stopped
- Only the essential digital power domain is ON and supplied at 1.0 V
- The bank RAM0 is kept in retention
- The other banks of RAM can be in retention or not, depending on the software configuration
- The low speed clock can be running or stopped, depending on the software configuration:
  - ON or OFF
  - Sourced by LSE or by LSI
- The RTC and the IWDG stay active, if enabled and the low speed clock is ON
- The I/Os pull-up and pull-down can be controlled during Deepstop mode, depending on the software configuration
- The radio wakeup block, including its timer, stays active (if enabled and the low speed clock is ON)
- Eight I/Os (PA4/ PA5/ PA6/ PA7/ PA8/ PA9/ PA10/ PA11) can be in output driving:
  - A static low or high level
  - The low speed clock
  - The RTC output

#### Possible wakeup sources are:

- The radio block is able to generate two events to wake up the system through its embedded wakeup timer running on a low speed clock:
  - Radio wakeup time is reached
  - CPU host wakeup time is reached
- The RTC can generate a wakeup event
- The IWDG can generate a reset event
- Up to 28 GPIOs are able to wake up the system (PA0 to PA15 and PB0 to PB11)

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At the wakeup, all the hardware resources located in the digital power domain that are OFF during the Deepstop mode, are reset. The CPU reboots. The wakeup reason is visible in the register of the power controller.

#### 3.8.3 Shutdown mode

The Shutdown mode is the least power-consuming mode.

The conditions to enter Shutdown mode are the same conditions needed to enter Deepstop mode except that the LPMS bit of the power controller unit is 1.

In Shutdown mode, the STM32WB0xxC is in ultralow power consumption: all voltage regulators, clocks, and the RF interface are not powered. The STM32WB0xxC can enter shutdown mode by internal software sequence. The only way to exit Shutdown mode is by asserting and deasserting the RSTN pin.

In shutdown mode:

- The system is powered down as both the regulators are OFF.
- The VDDIO power domain is ON.
- All the clocks are OFF, LSI, and LSE are OFF.
- The I/Os pull-up and pull-down can be controlled during Shutdown mode, depending on the software configuration.
- The only wakeup source is a low pulse on the RSTN pin.

The exit from Shutdown is similar to a POR startup. The PDR feature can be enabled or disabled during Shutdown.

#### 3.9 Peripheral interconnect matrix

#### 3.9.1 System architecture

The main system consists of 32-bit multilayer AHB bus matrix that interconnects:

- Three masters:
  - CPU (Cortex®-M0+) core S-bus
  - DMA1
  - Radio system
- Nine slaves:
  - Internal Flash memory on CPU (Cortex<sup>®</sup>-M0+) S bus
  - Internal SRAM0 (16 KB)
  - Internal SRAM1 (16 KB)
  - Internal SRAM2 (16 KB)
  - Internal SRAM3 (16 KB)
  - APB0 peripherals (through an AHB to APB bridge)
  - APB1 peripherals (through an AHB to APB bridge)
  - AHB0 peripherals
  - AHBRF including AHB to APB bridge and radio peripherals (connected to APB2)

The bus matrix provides access from a master to a slave, enabling concurrent access and efficient operation even when several high-speed peripherals work simultaneously.

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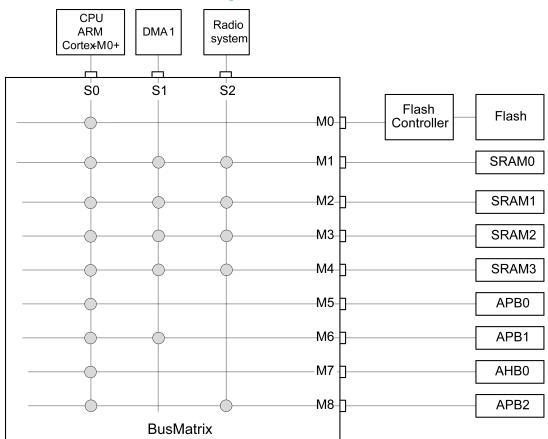


Figure 5. Bus matrix

### 3.10 Reset and clock controller (RCC)

#### 3.10.1 Reset management

The STM32WB0xxC offers two different resets:

• The PORESETn: this reset is provided by the low power management unit (LPMU) analog block and corresponds to a POR or PDR root cause. It is linked to power voltage ramp-up or ramp-down. This reset impacts all resources of the STM32WB0xxC. The exit from Shutdown mode is equivalent to a POR and thus generates a PORESETn. The PORESETn signal is active when the power supply of the device is below a threshold value or when the regulator does not provide the target voltage.

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- The PADRESETn (system reset): this reset is built through several sources:
  - PORESETn
  - Reset due to the watchdog

The STM32WB0xxC device embeds a watchdog timer, which may be used to recover from software crashes

Reset due to CPU lockup

The Cortex®-M0+ generates a lockup to indicate the core is in the lock-up state resulting from an unrecoverable exception. The lock-up reset is masked if a debugger is connected to the Cortex®-M0+

Software system reset

The system reset request is generated by the debug circuitry of the Cortex®-M0+. The debugger sets the SYSRESETREQ bit of the application interrupt and reset control register (AIRCR). This system reset request through the AIRCR can also be done by the embedded software (into the hard fault handler for instance)

Reset from the RSTN external pin
 The RSTN pin toggles to inform that a reset has occurred

This PADRESETn resets all resources of the STM32WB0xxC, except:

- Debug features
- · Flash memory controller key management
- RTC timer
- Power controller unit
- Part of the RCC registers

The pulse generator guarantees a minimum reset pulse duration of 20 µs for each internal reset source. In case of reset from the RSTN external pad, the reset pulse is generated when the pad is asserted low.

#### 3.10.2 Clock management

Three different clock sources may be used to drive the system clock of the STM32WB0xxC:

- HSI: high speed internal 64 MHz RC oscillator
- PLL64M: 64 MHz PLL clock
- HSE: high speed 32 MHz external crystal

The STM32WB0xxC also has a low speed clock tree used by some timers in the radio, RTC, and IWDG.

Four different clock sources can be used for this low speed clock tree:

- Low speed internal (LSI): low speed and low drift internal RC with a fixed frequency between 24 kHz and 49 kHz depending on the sample
- Low speed external (LSE) from:
  - An external crystal 32.768 kHz
  - A single-ended 32.738 kHz input signal
- A 32 kHz clock (CLK\_16 MHz/512 in Figure 6. Clock tree) obtained by dividing HSI or HSE. In this case, the slow clock is not available in Deepstop low power mode
- LSI\_LPMU: 32 kHz clock used by the low power management unit (LPMU) analog block.

By default, after a system reset, all low-speed sources are OFF.

Both the activation and the selection of the slow clock are relevant during the Deepstop mode and at wakeup as the slow clock generates a clock for the timers involved in wakeup event generation.

The HSI and the PLL64M clocks are provided by the same analog block called RC64MPLL. The 64 MHz clock output by this block can be:

- A nonaccurate clock when no external XO provides an input clock to this block (HSI)
- An accurate clock when the external XO provides the 32 MHz and once its internal PLL is locked (PLL64M)

This fast clock source is used to generate all the fast clocks of the device through dividers. After reset, the CLK\_SYS is divided by four to provide a 16 MHz to the whole system (CPU, DMA, memories, and peripherals).

This fast clock source is also used to generate several internal fast clocks in the system:

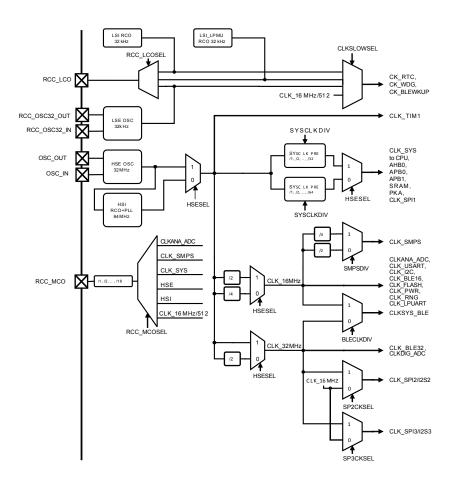
Always 32 MHz requested by a few peripherals like the radio

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Always 16 MHz requested by a few peripherals like serial interfaces (to maintain fixed the baud rate while
the system clock is switching from one frequency to another) or like the flash memory controller and radio
(to have a fixed reference clock to manage delays)

Figure 6. Clock tree



758107V

It is possible to output some internal clocks on external pads:

- The low speed clocks can be output on the RCC\_LCO I/O
- The high speed clocks can be output on the RCC\_MCO I/O

This is possible by programming the associated I/O in the correct alternate function.

Most of the peripherals only use the system clock except:

- I<sup>2</sup>C, USART, LPUART: they always use an a16 MHz clock to have a fixed reference clock for baud rate management. The goal is to allow the CPU to boost or slow down the system clock (depending on ongoing activities) without impacting a potential ongoing serial interface transfer on external I/Os
- SPI: when the I2S mode is used, the baud rate is always managed through the 16 MHz or 32 MHz clock. When modes other than the I2S run, the baud rate is managed by the system clock. This implies that its baud rate is impacted by dynamic system clock frequency changes
- RNG: in parallel to the system clock, the RNG always uses a 16 MHz clock to generate at a constant frequency the random number whatever the system clock frequency
- Flash memory controller: in parallel to the system clock, the flash memory controller always uses a 16 MHz clock to generate specific delays required by the flash memory during programming and erase operations for example
- PKA: in parallel to the system clock, the PKA uses a clock at half of the system clock frequency

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- Radio: it does not directly use the system clock for its APB/AHB interfaces, but the system clock with a potential divider (1 or 2 or 4). In parallel, the radio always uses 16 MHz and always 32 MHz for modulator, demodulator and to have a fixed reference clock to manage specific delays
- ADC: in parallel to the system clock, ADC uses a 64 MHz prescaled clock running at 16 MHz

#### 3.11 General purpose inputs/outputs (GPIO)

Each of the GPIO pins can be configured by software as output (push-pull or open-drain), as input (with or without pull-up or pull-down) or as peripheral alternate function. Most of the GPIO pins are shared with digital or analog alternate functions. Fast I/O toggling can be achieved thanks to their mapping on the AHB0 bus.

The I/Os alternate function configuration can be locked if needed following a specific sequence in order to avoid spurious writing to the I/Os registers.

#### 3.11.1 Tx and Rx event alert

The STM32WB0xxC is provided with the RADIO\_TX\_SEQUENCE and RADIO\_RX\_SEQUENCE signals which alert, respectively, transmission and reception activities.

A signal can be enabled for Tx and Rx on two pins, through alternate functions:

- RADIO TX SEQUENCE is available on PA10 (AF2) or PB15 (AF1).
- RADIO\_RX\_SEQUENCE is available on PA8 (AF2) or PA11 (AF2).

The signal is high when the radio is in Tx (or Rx), low otherwise.

The signals can be used to control external antenna switching and support coexistence with other wireless technologies.

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#### 3.12 Direct memory access (DMA)

The DMA is used in order to provide high-speed data transfer between peripherals and memory as well as memory-to-memory. Data can be quickly moved by DMA without any CPU actions. In this manner, CPU resources are free for other operations.

The DMA controller has eight channels in total. Each has an arbiter to handle the priority among DMA requests. DMA main features are:

- Eight independently configurable channels (requests)
- Each of the eight channels is connected to dedicated hardware DMA requests, software trigger is also supported on each channel. This configuration is done by software
- Priorities among requests from channels of DMA are software programmable (four levels consisting of very high, high, medium, low) or hardware in case of equality (request 1 has priority over request 2, and so on)
- Independent source and destination transfer size (byte, half word, word), emulating packing and unpacking. Source/destination addresses must be aligned on the data size
- Support for circular buffer management
- Three event flags (DMA half transfer, DMA transfer complete and DMA transfer error) logically ORed together in a single interrupt request for each channel
- Memory-to-memory transfer (RAM only)
- Peripheral-to-memory and memory-to-peripheral, and peripheral-to-peripheral transfers
- Access to SRAMs and APB1 peripherals as source and destination
- Programmable number of data to be transferred: up to 65536

#### 3.13 Interrupts and events

#### 3.13.1 Nested vectored interrupt controller (NVIC)

The interrupts are handled by the Cortex®-M0+ nested vector interrupt controller (NVIC). NVIC controls specific Cortex®-M0+ interrupts as well as the STM32WB0xxC peripheral interrupts.

The NVIC benefits are the following:

- Nested vectored interrupt controller that is an integral part of the Arm® Cortex®-M0+
- A tightly coupled interrupt controller provides low interrupt latency
- Control system exceptions and peripheral interrupts
- NVIC supports 32 vectored interrupts
- Four programmable interrupt priority levels with hardware priority level masking
- Software interrupt generation using the Arm® exceptions SVCall and PendSV
- Support for NMI
- Arm® Cortex® M0+ vector table offset register VTOR implemented

NVIC hardware block provides flexible interrupt management features with minimal interrupt latency.

#### 3.14 Analog digital converter (ADC)

The STM32WB0xxC embeds a 12-bit ADC. The ADC consists of a 12-bit successive approximation analog-to-digital converter (SAR) with 2 x 8 multiplexed channels allowing measurements of up to eight external sources and up to two internal sources.

The ADC main features are:

- Conversion frequency is up to 1 Msps
- Three input voltage ranges are supported (0 1.2 V, 0 2.4 V, 0 3.6 V)
- Up to eight analog single-ended channels or four analog differential inputs or a mix of both
- Temperature sensor conversion
- Battery level conversion up to 3.6 V
- ADC continuous or single mode conversion is possible
- ADC down-sampler for multi-purpose applications to improve analog performance while off-loading the CPU (ratio adjustable from 1 to 128)

A watchdog feature to inform when data is outside thresholds

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- DMA capability
- Interrupt sources with flags.

#### 3.14.1 Digital MEMS microphone interface

The digital MEMS microphone interface aims to interconnect with an external digital MEMS microphone. The STM32WB0xxC can configure two GPIOs as a PDM interface. The PDM\_CLK provides the clock output signal, programmable in frequency, to the microphone, while the PDM\_DATA receives the PDM output data from the microphone. The decimation filter and the digital control resources are used to handle the PDM data stream.

#### 3.14.2 Analog microphone interface

The analog microphone interface is dedicated to the analog microphone signal. The input audio signal is amplified with a programmable gain amplifier (PGA) from 0 dB to 30 dB, then the data stream is sampled by ADC and processed through the decimation filter.

#### 3.14.3 Temperature sensor

The temperature sensor (TS) generates a voltage that varies linearly with temperature. The temperature sensor is internally connected to the ADC input channel, which is used to convert the sensor output voltage into a digital value.

To improve the accuracy of the temperature sensor measurement, each device is individually factory-calibrated by ST. The temperature sensor factory calibration data are stored by ST in the system memory area, accessible in read-only mode.

#### 3.15 True random number generator (RNG)

An RNG, or random number generator, is based on continuous analog noise and provides a 16-bit value to the host upon being read. The minimum period is  $1.25~\mu s$ , which corresponds to 20~RNG clock cycles between two consecutive random numbers.

#### 3.16 Timers and watchdog

The STM32WB0xxC includes one advanced 16-bit timer, one watchdog timer, and a SysTick timer.

#### 3.16.1 Advanced control timer (TIM1)

The advanced-control timer can be considered as a three-phase PWM multiplexed on six channels. The six channels have complementary PWM outputs with programmable inserted dead-times.

They can also be used as general-purpose timers for:

- Input capture (except channels 5 and 6)
- Output compare
- PWM generation (edge and center-aligned mode)
- One-pulse mode output

#### 3.16.2 Independent watchdog (IWDG)

The independent watchdog is based on a 12-bit downcounter and 8-bit prescaler. It is clocked from the LS clock and it can operate in Deepstop mode. It can also be used as a watchdog to reset the device when a problem occurs.

#### 3.16.3 SysTick timer

This timer is dedicated to real-time operating systems, but could also be used as a standard down counter. It features:

- A 24-bit down counter
- Autoreload capability
- Maskable system interrupt generation when the counter reaches 0

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#### 3.17 Real-time clock (RTC), tamper and backup registers

#### 3.17.1 Real-time clock (RTC)

The RTC is an independent BCD timer/counter. The RTC provides a time of day/clock/calendar with programmable alarm interrupt. RTC includes also a periodic programmable wakeup flag with interrupt capability. The RTC provides an automatic wakeup to manage all low power modes.

Two 32-bit registers contain seconds, minutes, hours (12- or 24-hour format), day (day of week), date (day of month), month, and year, expressed in binary coded decimal format (BCD). The sub-second value is also available in binary format. Compensations for 28-, 29- (leap year), 30-, and 31-day months are performed automatically. Daylight saving time compensation can also be performed. Additional 32-bit registers contain the programmable alarm sub seconds, seconds, minutes, hours, day, and date.

A digital calibration circuit with 0.95 ppm resolution is available to compensate for quartz crystal inaccuracy. After power-on reset, all RTC registers are protected against possible parasitic write accesses. As long as the supply voltage remains in the operating range, the RTC never stops, regardless of the device status (Run mode, low power mode or under system reset). The RTC counter does not freeze when CPU is halted by a debugger.

#### 3.18 Inter-integrated circuit interface (I2C)

The STM32WB0xxC embeds two I2Cs. The I<sup>2</sup>C bus interface handles communications between the microcontroller and the serial I<sup>2</sup>C bus. It controls all I<sup>2</sup>C bus-specific sequencing, protocol, arbitration, and timing. The I2C peripheral supports:

- I<sup>2</sup>C bus specification and user manual rev. 5 compatibilities:
  - Target and controller modes
  - Multicontroller capability
  - Standard mode (Sm), with a bitrate up to 100 Kbit/s
  - Fast mode (Fm), with a bitrate up to 400 Kbit/s
  - Fast mode plus (Fm+), with a bitrate up to 1 Mbit/s and 20 mA output driver I/Os
  - 7-bit and 10-bit addressing mode
  - Multiple 7-bit target addresses (two addresses, 1 with configurable mask)
  - All 7-bit address acknowledge mode
  - General call
  - Programmable setup and hold times
  - Easy to use event management
  - Optional clock stretching
  - Software reset
- System management bus (SMBus) specification rev 2.0 compatibility:
  - Hardware PEC (Packet Error Checking) generation and verification with ACK control
  - Address resolution protocol (ARP) support
  - Host and device support
  - SMBus alert
  - Timeouts and idle condition detection
- Power system management protocol (PMBus™) specification Rev. 1.1 compatibility
- Independent clock: a choice of independent clock sources allowing the I<sup>2</sup>C communication speed to be independent from the PCLK reprogramming
- Programmable analog and digital noise filters
- 1-byte buffer with DMA capability

#### 3.19 Universal synchronous/asynchronous receiver transmitter (USART/UART)

USART offers flexible full-duplex data exchange with external equipment requiring an industry standard NRZ asynchronous serial data format. USART is able to communicate with a speed up to 2 Mbit/s. Furthermore, USART is able to detect and automatically set its own baud rate, based on the reception of a single character. The USART peripheral supports:

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- Synchronous one-way communication
- Half-duplex single wire communication
- Local interconnection network (LIN) master/slave capability
- Smart card mode, ISO 7816 compliant protocol
- IrDA (infrared data association) SIR ENDEC specifications
- Modem operations (CTS/RTS)
- RS485 driver enable
- Multiprocessor communications
- SPI-like communication capability

High speed data communication is possible by using DMA (direct memory access) for multibuffer configuration.

#### 3.19.1 Embedded UART bootloader

The STM32WB0xxC has a preprogrammed bootloader supporting the UART protocol with automatic baud rate detection. The main features of the embedded bootloader are:

- Auto baud rate detection up to 1 Mbps
- · Flash mass erase, section erase
- Flash programming
- Flash readout protection enable/disable

The preprogrammed bootloader is an application, which is stored in the STM32WB0xxC internal ROM at manufacturing time by STMicroelectronics. This application allows upgrading the flash device with a user application using a serial communication channel (UART).

The bootloader is activated by hardware by forcing PA10 high during hardware reset, otherwise, application residing in flash is launched.

#### 3.20 LPUART

LPUART is a UART which allows bidirectional UART communications. It supports half-duplex single wire communications and modem operations (CTS/RTS). It also supports multiprocessor communications. DMA (direct memory access) can be used for data transmission/reception.

#### 3.21 Serial peripheral interface (SPI)

The STM32WB0xxC has three SPI interfaces (SPI1, SPI2, SPI3) allowing communication up to 32 Mbit/s in both controller and target modes. The SPI peripheral supports:

- Controller or target operation
- Multimaster support
- Full-duplex synchronous transfers on three lines
- Half-duplex synchronous transfer on two lines (with bidirectional data line)
- Simplex synchronous transfers on two lines (with unidirectional data line)
- Serial communication with external devices
- NSS management by hardware or software for both controller and target: dynamic change of controller/ target operations
- SPI Motorola support
- SPI TI mode support
- Hardware CRC features for reliable communication

All SPI interfaces can be served by the DMA controller.

#### 3.21.1 Inter-IC sound (I2S)

The STM32WB0xxC SPI interfaces: SPI2 and SPI3 support the I2S protocol. The I2S interface can operate in target or controller mode with half-duplex communication. It can address four different audio standards:

- Philips I2S standard
- MSB-justified standards (left-justified)
- LSB-justified standards (right-justified)

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Phase-change memory standard.

The I2S interfaces DMA capability for transmission and reception.

#### 3.22 Development support

#### 3.22.1 Serial wire debug port

The STM32WB0xxC embeds an Arm SWD interface that allows interactive debugging and programming of the device. The interface is composed of only two pins: DEBUG\_SWDIO and DEBUG\_SWCLK. The enhanced debugging features for developers allow up to four breakpoints and up to two watchpoints.

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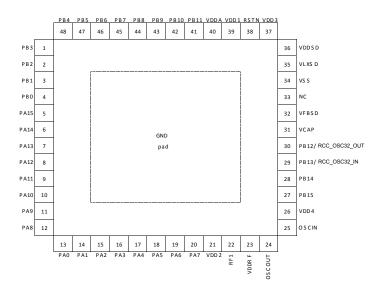
## 4 Pinouts/ballouts, pin description, and alternate functions

#### 4.1 Pinout/ballout schematics

The STM32WB0xxC comes in three package versions: VFQFPN48 offering 32 GPIOs, WLCSP49 offering 30 GPIOs and VFQFPN32 offering 20 GPIOs.

Figure 7. VFQFPN48 pinout

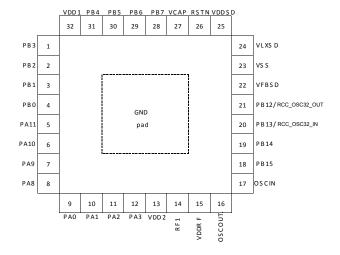
Package top view



DT58108V2

Figure 8. VFQFPN32 pinout

Package top view



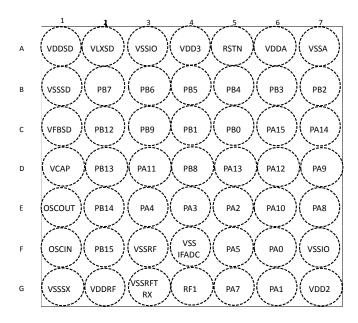
DT58109V2

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#### Figure 9. WLCSP49 pinout

#### Package top view



DT58110V1

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## 4.2 Pin description



STM32WB06xC STM32WB07xC Pinouts/ballouts, pin description, and alternate functions

Table 5. Legend/abbreviations used in the pinout table

| Name          | Abbreviation                                 | Definition                                                                                     |  |
|---------------|----------------------------------------------|------------------------------------------------------------------------------------------------|--|
| Pin name      | Unless otherwise specified in brackets below | the pin name, the pin function during and after reset is the same as the actual pin name.      |  |
|               | А                                            | Analog-only input                                                                              |  |
|               | 1                                            | Input-only pin                                                                                 |  |
| Pin type      | I/O                                          | Input/output pin                                                                               |  |
|               | 0                                            | Output-only pin                                                                                |  |
|               | S                                            | Supply pin                                                                                     |  |
|               | DDR                                          | DDR 1.5 V or 1.2 V I/O for DDR3, DDR3L, LPDDR2/LPDDR3, DDR4, and LPDDR4 interfaces             |  |
|               | DSI                                          | 1.2 V I/O for DSI interface                                                                    |  |
|               | FT                                           | 5 V-tolerant I/O                                                                               |  |
|               | FTP                                          | 5 V-tolerant I/O with fixed pull-down                                                          |  |
|               | FTPD                                         | 5 V-tolerant I/O with fixed programmable pull-down                                             |  |
|               | FTU                                          | 5 V-tolerant I/O with fixed pull-up                                                            |  |
|               | RF                                           | RF I/O                                                                                         |  |
|               | TC                                           | 3.6 V-capable I/O with ESS diode connected to V <sub>DD</sub>                                  |  |
|               | TT                                           | 3.6 V-tolerant I/O                                                                             |  |
| I/O structure | ТТа                                          | 3.6 V-tolerant I/O with internal clamping to V <sub>DDA</sub>                                  |  |
| i/O structure | В                                            | Dedicated BOOT0 pin                                                                            |  |
|               | POR                                          | External power on reset pin with embedded weak pull-up resistor, powered from V <sub>DDA</sub> |  |
|               | RST                                          | Bidirectional reset pin with embedded weak pull-up resistor                                    |  |
|               |                                              | Options for TT and FT I/Os <sup>(1)</sup>                                                      |  |
|               | _a                                           | I/O with analog switch function supplied by V <sub>DDA</sub>                                   |  |
|               | _c                                           | USB Type-C® power delivery capable I/O                                                         |  |
|               | _d                                           | USB Type-C® power delivery dead battery function I/O                                           |  |
|               | _e                                           | I/O with switchable diode to V <sub>DD</sub>                                                   |  |
|               | _f                                           | I2C Fm+ capable I/O                                                                            |  |
|               | _h                                           | High-speed low-voltage I/O                                                                     |  |
|               |                                              |                                                                                                |  |

| <b>Y</b> I |  |
|------------|--|
|            |  |
| •          |  |

| Name          | Name Abbreviation    |                                                                  | Definition                                                                                                                                                                                      |  |
|---------------|----------------------|------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--|
|               |                      | _l                                                               | I/O with LCD function supplied by V <sub>LCD</sub>                                                                                                                                              |  |
|               |                      | _p                                                               | I/O with differential clock capability CLKP/CLKN                                                                                                                                                |  |
| I/O structure |                      | _s                                                               | I/O supplied only by V <sub>DDIO2</sub>                                                                                                                                                         |  |
| no structure  |                      | _t                                                               | Tamper I/O                                                                                                                                                                                      |  |
|               |                      | _u                                                               | I/O with USB function, supplied by V <sub>DDUSB</sub>                                                                                                                                           |  |
|               |                      | _v                                                               | Very high-speed I/O                                                                                                                                                                             |  |
| Notes         |                      |                                                                  | r reset, with the exception of PA2 (DEBUG_SWDIO) and PA3 (DEBUG_SWCLK) pins on pullup and alternate function pulldown. By default, all I/Os pull-ups/pull-downs are PUCRx/PWRC_PDCRx registers. |  |
| Din functions | Alternate functions  | Functions selected through GPIOx_AFR registers                   |                                                                                                                                                                                                 |  |
| Pin functions | Additional functions | Functions directly selected/enabled through peripheral registers |                                                                                                                                                                                                 |  |

<sup>1.</sup> The related I/O structures in the table below are a concatenation of various options. Examples: FT\_hat, FT\_fs, FT\_u, TT\_a.

#### Table 6. STM32WB0xxC pin/ball definition

|          | Pin number |         | Pin name               | <b>-</b> |               |                                                                   |                                             |
|----------|------------|---------|------------------------|----------|---------------|-------------------------------------------------------------------|---------------------------------------------|
| VFQFPN32 | VFQFPN48   | WLCSP49 | (function after reset) | Pin type | I/O structure | Alternate functions                                               | Additional functions                        |
| 1        | 1          | B6      | PB3                    | I/O      | FT_a          | USART_CTS, LPUART_TX, TIM1_CH4                                    | ADC_VINP0,PWR_WKUP3                         |
| 2        | 2          | B7      | PB2                    | I/O      | FT_a          | USART_RTS_DE, PDM_DATA, TIM1_CH3                                  | ADC_VINM0, PWR_WKUP2                        |
| 3        | 3          | C4      | PB1                    | I/O      | FT_a          | SPI1_NSS, PDM_CLK, TIM1_ETR                                       | ADC_VINP1, PWR_WKUP1                        |
| 4        | 4          | C5      | PB0                    | I/O      | FT_a          | USART_RX, LPUART_RTS_DE, TIM1_CH2N                                | ADC_VINM1, PWR_WKUP0                        |
| -        | 5          | C6      | PA15                   | I/O      | FT_a          | I2C2_SMBA, SPI1_MOSI, TIM1_BKIN2                                  | ADC_VINP2, PWR_WKUP27                       |
| -        | 6          | C7      | PA14                   | I/O      | FT_a          | I2C2_SDA, SPI1_MISO, TIM1_BKIN                                    | ADC_VINM2, PWR_WKUP26                       |
| -        | 7          | D5      | PA13                   | I/O      | FT_a          | I2C2_SCL, SPI1_SCK, SPI2_MISO,<br>TIM1_ETR                        | ADC_VINP3, PWR_WKUP25                       |
| -        | 8          | D6      | PA12                   | I/O      | FT_a          | I2C1_SMBA, SPI1_NSS,<br>SPI2_MOSI,TIM1_CH1, I2S2_SD               | ADC_VINM3, PWR_WKUP24                       |
| 5        | 9          | D3      | PA11                   | I/O      | FT            | RCC_MCO, SPI1_NSS,<br>RADIO_RX_SEQUENCE, SPI3_MOSI,<br>I2S3_SD    | PWR_WKUP11, GPIO in Deepstop,<br>RTC_OUT    |
| 6        | 10         | E6      | PA10                   | I/O      | FT            | RCC_LCO, SPI1_MISO,<br>RADIO_TX_SEQUENCE, I2S3_MCK                | BOOT, PWR_WKUP10, GPIO in Deepstop, RCC_LCO |
| 7        | 11         | D7      | PA9                    | I/O      | FT            | USART_TX, SPI1_SCK, RTC_OUT, SPI3_NSS, TIM1_CH4, I2S3_WS          | PWR_WKUP9, GPIO in Deepstop, RCC_LCO        |
| 8        | 12         | E7      | PA8                    | I/O      | FT            | USART_RX, SPI1_MOSI,<br>RADIO_RX_SEQUENCE, SPI3_MISO,<br>TIM1_CH3 | PWR_WKUP8, GPIO in Deepstop, RTC_OUT        |
| 9        | 13         | F6      | PA0                    | I/O      | FT_f          | I2C1_SCL, USART_CTS, TIM1_CH3,<br>I2S2_MCK                        | PWR_WKUP12                                  |
| 10       | 14         | G6      | PA1                    | I/O      | FT_f          | I2C1_SDA, SPI2_MISO, USART_TX,<br>TIM1_CH4                        | PWR_WKUP13                                  |
| 11       | 15         | E5      | PA2                    | I/O      | FT            | DEBUG_SWDIO, USART_CK, TIM_BKIN, I2S3_MCK                         | PWR_WKUP14                                  |
| 12       | 16         | E4      | PA3                    | I/O      | FT            | DEBUG_SWCLK, USART_RTS_DE,<br>TIM_BKIN2, SPI3_SCK, I2S3_SCK       | PWR_WKUP15                                  |
| -        | 17         | E3      | PA4                    | I/O      | FT            | RCC_LCO, SPI2_NSS, LPUART_TX,<br>TIM1_CH1, I2S2_WS                | PWR_WKUP16, GPIO in Deepstop,<br>RCC_LCO    |
| -        | 18         | F5      | PA5                    | I/O      | FT            | RCC_MCO, SPI2_SCK, LPUART_RX,<br>TIM1_CH2, I2S2_SCK               | PWR_WKUP17, GPIO in Deepstop,<br>RCC_LCO    |
| -        | 19         | -       | PA6                    | I/O      | FT            | LPUART_CTS, SPI2_MOSI, SPI2_NSS,<br>TIM1_CH1, I2S2_SD, I2S2_WS    | PWR_WKUP18, GPIO in Deepstop,<br>RCC_LCO    |



|          | Pin number |         | Pin number             |          | Pin name      |                                                                |                                          |  |  |
|----------|------------|---------|------------------------|----------|---------------|----------------------------------------------------------------|------------------------------------------|--|--|
| VFQFPN32 | VFQFPN48   | WLCSP49 | (function after reset) | Pin type | I/O structure | Alternate functions                                            | Additional functions                     |  |  |
| -        | 20         | G5      | PA7                    | I/O      | FT            | LPUART_RTS_DE, SPI2_MISO, SPI2_SCK,<br>TIM1_CH2, I2S2_SCK      | PWR_WKUP19, GPIO in Deepstop,<br>RTC_OUT |  |  |
| 13       | 21         | G7      | VDD2                   | S        | -             | -                                                              | 1.7-3.6 battery voltage input            |  |  |
| 14       | 22         | G4      | RF1                    | I/O      | RF            | -                                                              | RF input/output. Impedance 50 $\Omega$   |  |  |
| 15       | 23         | G2      | VDDRF                  | S        | -             | -                                                              | 1.7-3.6 battery voltage input            |  |  |
| 16       | 24         | E1      | OSCOUT                 | I/O      | RF            | -                                                              | 32 MHz crystal                           |  |  |
| 17       | 25         | F1      | OSCIN                  | I/O      | RF            | -                                                              | 32 MHz crystal                           |  |  |
| -        | 26         | -       | VDD4                   | S        | -             | -                                                              | 1.7-3.6 battery voltage input            |  |  |
| 18       | 27         | F2      | PB15                   | I/O      | FT            | I2C1_SMBA, RADIO_TX_SEQUENCE,<br>RCC_MCO, TIM1_CH4N, USART_TX  | -                                        |  |  |
| 19       | 28         | E2      | PB14                   | I/O      | FT_a          | SPI1_MOSI, I2C2_SDA, TIM1_ETR,<br>TIM1_CH3N, USART_RX          | PWR_PVD_IN                               |  |  |
| 20       | 29         | D2      | PB13                   | I/O      | FT            | SPI1_MISO, I2C2_SCL, PDM_CLK,<br>TIM1_BKIN2, TIM1_CH4          | RCC_OSC32_OUT                            |  |  |
| 21       | 30         | C2      | PB12                   | I/O      | FT            | SPI1_SCK, RCC_LCO, PDM_DATA,<br>TIM1_BKIN, TIM1_CH3            | RCC_OSC32_IN                             |  |  |
| 27       | 31         | D1      | VCAP                   | S        | -             | -                                                              | 1.2 Vdigital core                        |  |  |
| 22       | 32         | C1      | VFBSD                  | S        | -             | -                                                              | SMPS output                              |  |  |
| -        | 33         | -       | NC                     | S        | -             | -                                                              | -                                        |  |  |
| 23       | 34         | B1      | VSSSD                  | S        | -             | -                                                              | SMPS Ground                              |  |  |
| 24       | 35         | A2      | VLXSD                  | S        | -             | -                                                              | SMPS input/output                        |  |  |
| 25       | 36         | A1      | VDDSD                  | S        | -             | -                                                              | 1.7-3.6 battery voltage input            |  |  |
| -        | 37         | A4      | VDD3                   | S        | -             | -                                                              | 1.7-3.6 battery voltage input            |  |  |
| 26       | 38         | A5      | RSTN                   | I/O      | RST           | -                                                              | Reset pin                                |  |  |
| 32       | 39         | -       | VDD1                   | S        | -             | -                                                              | 1.7-3.6 battery voltage input            |  |  |
| -        | 40         | A6      | VDDA                   | S        | -             | -                                                              | 1.2 V analog ADC core                    |  |  |
| -        | 41         | -       | PB11                   | I/O      | FT            | SPI1_SCK, SPI2_NSS, I2C1_SCL,<br>TIM1_CH1, TIM1_CH4N, I2S2_WS  | PWR_WKUP23                               |  |  |
| -        | 42         | -       | PB10                   | I/O      | FT            | SPI1_NSS, SPI2_SCK, I2C1_SDA,<br>TIM1_CH2, TIM1_CH3N, I2S2_SCK | PWR_WKUP22                               |  |  |
| -        | 43         | C3      | PB9                    | I/O      | FT            | USART_TX, LPUART_CTS, TIM1_CH1N,<br>TIM1_CH2N, I2S2_MCK        | PWR_WKUP21                               |  |  |

| 7 |  |
|---|--|
| 3 |  |

| Pin number  |             | Pin name | <b>.</b> .             |          |                                         |                                                               |                        |  |  |
|-------------|-------------|----------|------------------------|----------|-----------------------------------------|---------------------------------------------------------------|------------------------|--|--|
| VFQFPN32    | VFQFPN48    | WLCSP49  | (function after reset) | Pin type | I/O structure                           | Alternate functions                                           | Additional functions   |  |  |
| -           | 44          | D4       | PB8                    | I/O      | FT                                      | USART_CK, LPUART_RX, TIM1_CH4,<br>TIM1_CH1N                   | PWR_WKUP20             |  |  |
| 28          | 45          | B2       | PB7                    | I/O      | FT_f I2C2_SDA, SPI2_SCK, LPUART_RX, PWF |                                                               |                        |  |  |
| 29          | 46          | В3       | PB6                    | I/O      | FT_f                                    | FT_f                                                          |                        |  |  |
| 30          | 47          | B4       | PB5                    | I/O      | TT                                      | LPUART_RX, SPI2_MOSI, PDM_CLK, I2S2_SD PGA_VBIAS_MIC(1), PWR_ |                        |  |  |
| 48          | 31          | B5       | PB4                    | I/O      | FT                                      | LPUART_TX, SPI2_MISO, PDM_DATA                                | PGA_VIN, PWR_WKUP4     |  |  |
| -           | -           | A7       | VSSA                   | S        | -                                       | -                                                             | Ground analog ADC core |  |  |
| -           | -           | A3       | VSSIO                  | S        | -                                       | -                                                             | Ground I/O             |  |  |
| -           | -           | F7       | VSSIO                  | S        | -                                       | -                                                             | Ground I/O             |  |  |
| -           | -           | F4       | VSSIFADC               | S        | -                                       | -                                                             | Ground analog RF       |  |  |
| -           | -           | G1       | VSSSX                  | S        | -                                       | -                                                             | Ground analog RF       |  |  |
| -           | -           | G3       | VSSRFTRX               | S        | -                                       | -                                                             | Ground analog RF       |  |  |
| -           | -           | F3       | VSSRF                  | S        | -                                       | -                                                             | Ground analog RF       |  |  |
| Exposed pad | Exposed pad | -        | GND                    | S        | -                                       | -                                                             | Ground                 |  |  |

<sup>1.</sup> This pin is not 5 V tolerant.

#### 4.3 **Alternate functions**

Table 7. Alternate function port A

|         |      | AF0                               | AF1                              | AF2                               | AF3                              | AF4        | AF5         | AF6 | AF7         |  |
|---------|------|-----------------------------------|----------------------------------|-----------------------------------|----------------------------------|------------|-------------|-----|-------------|--|
| Po      | ort  | I2C1/I2C2/SYS_AF<br>LPUART/ USART | SPI1/SPI2/ SYS_AF/<br>USART/I2S2 | SPI1/SPI2/RTC USART/<br>TIM/ I2S2 | SPI2/ SPI3 LPUART/<br>I2S2/ I2S3 | TIM1       | SYS_AF      | -   | SYS_AF      |  |
|         | PA0  | I2C1_SCL                          | USART_CTS                        | I2S2_MCK                          | -                                | TIM1_CH3   | -           | -   | -           |  |
|         | PA1  | I2C1_SDA                          | SPI2_MISO                        | USART_TX                          | -                                | TIM1_CH4   | -           | -   | -           |  |
|         | PA2  | DEBUG_SWDIO                       | USART_CK                         | TIM_BKIN                          | I2S3_MCK                         | -          | DEBUG_SWDIO | -   | DEBUG_SWDIO |  |
|         | PA3  | DEBUG_SWCLK                       | USART_RTS_DE                     | TIM_BKIN2                         | SPI3_SCK/I2S3_SCK                | -          | DEBUG_SWCLK | -   | DEBUG_SWCLK |  |
|         | PA4  | RCC_LCO                           | SPI2_NSS/I2S2_WS                 | -                                 | LPUART_TX                        | TIM1_CH1   | -           | -   | -           |  |
|         | PA5  | RCC_MCO                           | SPI2_SCK/I2S2_SCK                | -                                 | LPUART_RX                        | TIM1_CH2   | -           | -   | -           |  |
|         | PA6  | LPUART_CTS                        | SPI2_MOSI/I2S2_SD                | -                                 | SPI2_NSS/I2S2_WS                 | TIM1_CH1   | -           | -   | -           |  |
| David A | PA7  | LPUART_RTS_DE                     | SPI2_MISO                        | -                                 | SPI2_SCK/I2S2_SCK                | TIM1_CH2   | -           | -   | -           |  |
| Port A  | PA8  | USART_RX                          | SPI1_MOSI                        | RADIO_RX_SEQUENCE                 | SPI3_MISO                        | TIM1_CH3   | -           | -   | -           |  |
|         | PA9  | USART_TX                          | SPI1_SCK                         | RTC_OUT                           | SPI3_NSS/I2S3_WS                 | TIM1_CH4   | -           | -   | -           |  |
|         | PA10 | RCC_LCO                           | SPI1_MISO                        | RADIO_TX_SEQUENCE                 | I2S3_MCK                         | -          | -           | -   | -           |  |
|         | PA11 | RCC_MCO                           | SPI1_NSS                         | RADIO_RX_SEQUENCE                 | SPI3_MOSI/I2S3_SD                | -          | -           | -   | -           |  |
|         | PA12 | I2C1_SMBA                         | DEBUG_SWDIO                      | SPI1_NSS                          | SPI2_MOSI/I2S2_SD                | TIM1_CH1   | -           | -   | -           |  |
|         | PA13 | I2C2_SCL                          | DEBUG_SWCLK                      | SPI1_SCK                          | SPI2_MISO                        | TIM1_ETR   | -           | -   | -           |  |
|         | PA14 | I2C2_SDA                          | -                                | SPI1_MISO                         | -                                | TIM1_BKIN  | -           | -   | -           |  |
|         | PA15 | I2C2_SMBA                         | -                                | SPI1_MOSI                         | -                                | TIM1_BKIN2 | -           | -   | -           |  |



Table 8. Alternate function port B

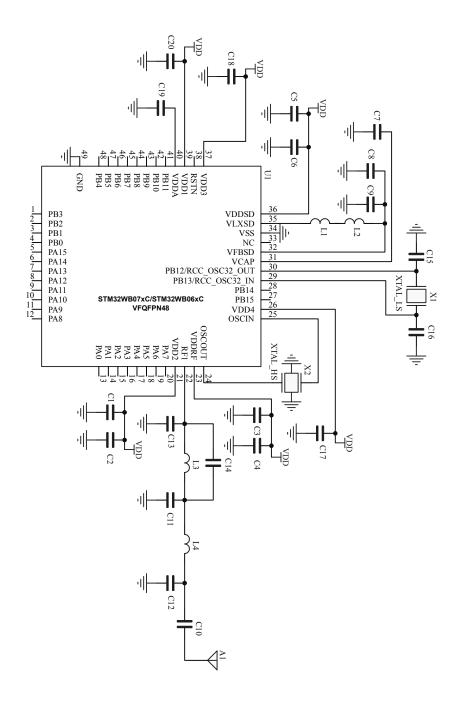
|        |      | AF0                    | AF1                              | AF2                                | AF3             | AF4       | AF5 | AF6 | AF7      |
|--------|------|------------------------|----------------------------------|------------------------------------|-----------------|-----------|-----|-----|----------|
| Po     | ort  | SPI1/I2C2 USART/LPUART | PDM/SYS_AF/I2C2 LPUART/SPI2/I2S2 | SPI2/I2C1/PDM TIM1/SYS_AF/<br>I2S2 | TIM1/PDM LPUART | TIM1      | -   | -   | USART    |
|        | PB0  | USART_RX               | LPUART_RTS_DE                    | -                                  | TIM1_CH2N       | -         | -   | -   | -        |
|        | PB1  | SPI1_NSS               | PDM_CLK                          | -                                  | TIM1_ETR        | -         | -   | -   | -        |
|        | PB2  | USART_RTS_DE           | PDM_DATA                         | -                                  | TIM1_CH3        | -         | -   | -   | -        |
|        | PB3  | USART_CTS              | LPUART_TX                        | -                                  | TIM1_CH4        | -         | -   | -   | -        |
|        | PB4  | LPUART_TX              | SPI2_MISO                        | -                                  | PDM_DATA        | -         | -   | -   | -        |
|        | PB5  | LPUART_RX              | SPI2_MOSI/I2S2_SD                | -                                  | PDM_CLK         | -         | -   | -   | -        |
| Port B | PB6  | I2C2_SCL               | SPI2_NSS/I2S2_WS                 | -                                  | LPUART_TX       | TIM1_CH1  | -   | -   | -        |
|        | PB7  | I2C2_SDA               | SPI2_SCK/IS2S_SCK                | -                                  | LPUART_RX       | TIM1_CH2  | -   | -   | -        |
|        | PB8  | USART_CK               | LPUART_RX                        | -                                  | TIM1_CH4        | TIM1_CH1N | -   | -   | -        |
|        | PB9  | USART_TX               | LPUART_CTS                       | I2S2_MCK                           | TIM1_CH1N       | TIM1_CH2N | -   | -   | -        |
|        | PB10 | SPI1_NSS               | SPI2_SCK/I2S2_SCKK               | I2C1_SDA                           | TIM1_CH2        | TIM1_CH3N | -   | -   | -        |
|        | PB11 | SPI1_SCK               | SPI2_NSS/I2S2_WS                 | I2C1_SCL                           | TIM1_CH1        | TIM1_CH4N | -   | -   | -        |
|        | PB12 | SPI1_SCK               | RCC_LCO                          | PDM_DATA                           | TIM1_BKIN       | TIM1_CH3  | -   | -   | -        |
|        | PB13 | SPI1_MISO              | I2C2_SCL                         | PDM_CLK                            | TIM1_BKIN2      | TIM1_CH4  | -   | -   | -        |
|        | PB14 | SPI1_MOSI              | I2C2_SDA                         | TIM1_ETR                           | TIM1_CH3N       | -         | -   | -   | USART_RX |
|        | PB15 | I2C1_SMBA              | RADIO_TX_SEQUENCE                | RCC_MCO                            | TIM1_CH4N       | -         | -   | -   | USART_TX |



# 5 Application circuits

The schematics below are purely indicative.

Figure 10. Application circuit: DC-DC converter, VFQFPN48 package



58112V

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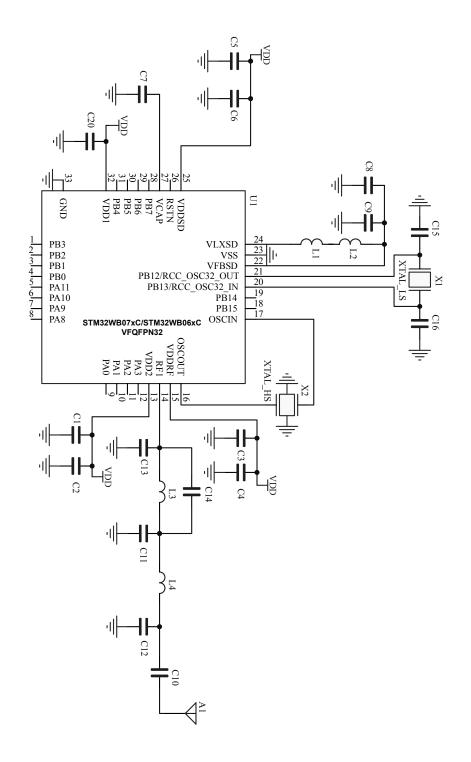


 $\times$ 1 C1 $\Box$ RCC\_OSC32\_OUT /PB12 RCC\_OSC32\_OUT /PB13  $\mathbb{G}$ G7 VDD2 VDD3 VDDRF A4 G2 VSSIO A7 VSSA В1 A1 VSSSD **VDDSD** STM32WB07xC/STM32WB06xC F4 VSSIFADC VSSRFTRX G3 WLCSP49 A6 VDDA VCAP A3 G1 D1 VSSIO VSSSX 6 OSCIN OSCOUT **RSTN** VLXSD VFBSD RF1  $C_2$ 2 C19 C13 C12 L3C8C14 L4 C11

Figure 11. Application circuit: DC-DC converter, WLCSP49 package

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Figure 12. Application circuit: DC-DC converter, VFQFPN32 package



DT58114V2



Table 9. Application circuit external components

| Component | Description                        |
|-----------|------------------------------------|
| C1        | Decoupling capacitor               |
| C2        | Decoupling capacitor               |
| C3        | Decoupling capacitor               |
| C4        | Decoupling capacitor               |
| C5        | Decoupling capacitor               |
| C6        | Decoupling capacitor               |
| C7        | Decoupling capacitor               |
| C8        | DC-DC converter output capacitor   |
| C9        | DC-DC converter output inductor    |
| C10       | DC block capacitor                 |
| C11       | RF matching capacitor              |
| C12       | RF matching capacitor              |
| C13       | RF matching capacitor              |
| C14       | RF matching capacitor              |
| C15       | 32 kHz crystal loading capacitor   |
| C16       | 32 kHz crystal loading capacitor   |
| C17       | Decoupling capacitor               |
| C18       | Decoupling capacitor               |
| C19       | Decoupling capacitor               |
| C20       | Decoupling capacitor               |
| L1        | DC-DC converter output inductor    |
| L2        | DC-DC converter filtering inductor |
| L3        | RF matching inductor               |
| L4        | RF matching inductor               |
| X1        | Low speed crystal                  |
| X2        | High speed crystal                 |
| U1        | STM32WB06xC/STM32WB07xC            |

Note: In order to make the board DC–DC OFF, the inductance L1 must be removed and the supply voltage must be applied to the VFBSD pin.

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### Electrical characteristics

#### 6.1 Parameter conditions

Unless otherwise specified, all voltages are referenced to V<sub>SS</sub>.

#### 6.1.1 Minimum and maximum values

Unless otherwise specified the minimum and maximum values are guaranteed in the worst conditions of junction temperature, supply voltage and frequencies by tests in production on 100 % of the devices with an junction temperature at  $T_J = 25$  °C and  $T_J = T_{Jmax}$  (given by the selected temperature range).

Data based on characterization results, design simulation and/or technology characteristics are indicated in the table footnotes. Based on characterization, the minimum and maximum values refer to sample tests and represent the mean value plus or minus three times the standard deviation (mean  $\pm 3\sigma$ ).

### 6.1.2 Typical values

Unless otherwise specified, typical data are based on  $T_J$  = 25 °C,  $V_{DD}$  = 3.3 V (for the 1.62 V  $\leq$  V<sub>DD</sub>  $\leq$  3.6 V voltage range). They are given only as design guidelines and are not tested.

Typical ADC accuracy values are determined by characterization of a batch of samples from a standard diffusion lot over the full temperature range, where 95% of the devices have an error less than or equal to the value indicated (mean  $\pm 2\sigma$ ).

#### 6.1.3 Typical curves

Unless otherwise specified, all typical curves are given only as design guidelines and are not tested.

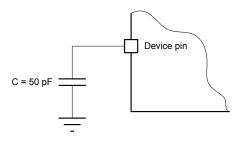
#### 6.1.4 Loading capacitor

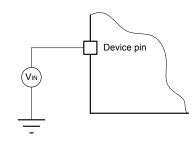
The loading conditions used for pin parameter measurement are shown in Figure 13.

#### 6.1.5 Pin input voltage

The input voltage measurement on a pin of the device is described in Figure 14.

Figure 13. Pin loading conditions





JT47494V1

Figure 14. Pin input voltage

## 6.2 Absolute maximum ratings

Stresses above the absolute maximum ratings listed in the tables below, may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these conditions is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

**Table 10. Voltage characteristics** 

| Symbol                               | Ratings                                                                    | Min. | Max.  | Unit |
|--------------------------------------|----------------------------------------------------------------------------|------|-------|------|
| VDD1, VDD2, VDD3, VDD4, VDDRF, VDDSD | DD3, VDD4, VDDRF, VDDSD DC-DC converter supply voltage input and output -0 |      | +3.9  | .,   |
| VCAP, VDDA                           | DC voltage on linear voltage regulator                                     | -0.3 | +1.32 | V    |

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| Symbol                                     | Ratings                                                              | Min. | Max.  | Unit |
|--------------------------------------------|----------------------------------------------------------------------|------|-------|------|
| FXTALOUT, FXTALIN                          | DC Voltage on HSE                                                    | -0.3 | +1.32 |      |
| PA0 to PA15, PB0 to PB4, PB6 to PB15       | DC voltage on digital input/output pins                              | -0.3 | +3.9  |      |
| VLXSD, VFBSD DC voltage on analog pins     |                                                                      |      | +3.9  | V    |
| RCC_OSC32_OUT/PB12, RCC_OSC32_IN/PB13, PB5 | DC voltage on XTAL pins and PGA_VBIAS_MIC                            | -0.3 | +3.6  |      |
| RF1                                        | DC voltage on RF pin                                                 |      | +1.4  | -    |
| $ \Delta V_{DD} $                          | Variations between different $V_{DDX}$ power pins of the same domain | -    | 50    | mV   |

Note:

All the main power and ground pins must always be connected to the external power supply, in the permitted range.

**Table 11. Current characteristics** 

| Symbol                 | Ratings                                                                |     | Unit |
|------------------------|------------------------------------------------------------------------|-----|------|
| $\Sigma IV_{DD}$       | Total current into sum of all VDD power lines (source)                 | 130 |      |
| ΣIV <sub>GND</sub>     | Total current out of sum of all ground lines (sink)                    | 130 |      |
| IV <sub>DD(PIN)</sub>  | IV <sub>DD(PIN)</sub> Maximum current into each VDD power pin (source) |     |      |
| IV <sub>GND(PIN)</sub> | N) Maximum current out of each ground pin (sink)                       |     | mA   |
| l                      | Output current sunk by any I/O and control pin                         | 20  | 1100 |
| I <sub>IO(PIN)</sub>   | Output current sourced by any I/O and control pin                      | 20  |      |
| Σliorpu                | Total output current sunk by sum of all I/Os and control pins          | 100 |      |
| ΣΙ <sub>ΙΟ(PIN)</sub>  | Total output current sourced by sum of all I/Os and control pins       | 100 |      |

**Table 12. Thermal characteristics** 

| Symbol           | Ratings                      | Value       | Unit |
|------------------|------------------------------|-------------|------|
| T <sub>STG</sub> | Storage temperature range    | -40 to -125 | °C   |
| TJ               | Maximum junction temperature | 125         | C    |

# 6.3 Operating conditions

# 6.3.1 General operating conditions

Table 13. General operating conditions

| Symbol              | Parameter                     | Conditions | Min. | Max. | Unit   |
|---------------------|-------------------------------|------------|------|------|--------|
| f <sub>HCLK</sub>   | Internal AHB clock frequency  | -          | 1    | 64   |        |
| f <sub>PCLK0</sub>  | Internal APB0 clock           | -          | 1    | 64   | MHz    |
| f <sub>PCLK1</sub>  | Internal APB1 clock frequency | -          | 1    | 64   | IVITIZ |
| f <sub>PCLK2</sub>  | Internal APB2 clock frequency | -          | 16   | 32   |        |
| V <sub>DD</sub>     | Standard operating voltage    | -          | 1.7  | 3.6  |        |
| V <sub>FBSMPS</sub> | SMPS feedback voltage         | -          | 1.4  | 3.6  | V      |
| V <sub>DDRF</sub>   | Minimum RF voltage            | -          | 1.7  | 3.6  |        |

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| Symbol          | Parameter                                                  | Conditions                | Min. | Max.    | Unit  |
|-----------------|------------------------------------------------------------|---------------------------|------|---------|-------|
| V <sub>IN</sub> | I/O input voltage                                          | -                         | -0.3 | VDD+0.3 | V     |
| P <sub>D</sub>  | Power dissipation at T <sub>A</sub> =105 °C <sup>(1)</sup> | VFQFPN48 package          | -    | 30      | mW    |
| ט י             | rower dissipation at 1 <sub>A</sub> =103°C                 | VFQFPN32 package          |      | 30      | IIIVV |
| T <sub>A</sub>  | Ambient temperature                                        | Maximum power dissipation | -40  | 105     | °C    |
| TJ              | Junction temperature range                                 | -                         | -40  | 105     | -     |

<sup>1.</sup>  $T_A$  cannot exceed the  $T_J$  max.

# 6.3.2 Summary of main performance

Table 14. Main performance SMPS ON

| Symbol               | Parameter                | Test conditions                                                          | Typ.<br>V <sub>DD</sub> = 1.8 V                       | Typ.<br>V <sub>DD</sub> = 3.3 V | Unit            |  |
|----------------------|--------------------------|--------------------------------------------------------------------------|-------------------------------------------------------|---------------------------------|-----------------|--|
|                      |                          | Shutdown                                                                 | 8                                                     | 19                              | nA              |  |
|                      |                          | Deepstop, no timer, wakeup<br>GPIO, RAM0 retained                        | 0.44                                                  | 0.46                            |                 |  |
|                      |                          | Deepstop, no timer, wakeup<br>GPIO, all RAM retained                     | 0.62                                                  | 0.64                            |                 |  |
|                      |                          | Deepstop (32 kHz LSI), RAM0 retained                                     | 0.94                                                  | 1.06                            |                 |  |
|                      |                          | Deepstop (32 kHz LSI), all RAMs retained                                 | 1.12                                                  | 1.24                            | μΑ              |  |
|                      | Core current consumption | Deepstop (32 kHz LSE), RAM0 retained                                     | 0.64                                                  | 0.75                            |                 |  |
| I <sub>CORE</sub>    |                          | Deepstop (32 kHz LSE), all RAM retained                                  | 0.83                                                  | 0.94                            |                 |  |
|                      |                          | CPU in Run (64 MHz).<br>Dhrystone, clock source PLL64                    | -                                                     | 2719                            |                 |  |
|                      |                          |                                                                          | CPU in Run (32 MHz).<br>Dhrystone, clock source PLL64 | -                               | 2188            |  |
|                      |                          | CPU in WFI (64 MHz), all peripherals off, clock source PLL64             | -                                                     | 1708                            | uA              |  |
|                      |                          | CPU in WFI (16 MHz), all peripherals off, clock source direct HSE        | -                                                     | 1092                            |                 |  |
|                      |                          | Radio Rx at sensitivity level                                            | -                                                     | 3350                            |                 |  |
|                      |                          | Radio Tx 0 dBm output power                                              | -                                                     | 4300                            |                 |  |
| I <sub>DYNAMIC</sub> | Dynamic current          | Computed value: (CPU 64 MHz<br>Dhrystone - CPU 32 MHz<br>Dhrystone) / 32 | -                                                     | 16.5                            | μ <b>A</b> /MHz |  |

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Table 15. Main performance SMPS bypassed

| Symbol            | Parameter                | Test conditions                                                            | Typ.<br>V <sub>DD</sub> = 1.8 V | Typ.<br>V <sub>DD</sub> = 3.3 V | Unit |
|-------------------|--------------------------|----------------------------------------------------------------------------|---------------------------------|---------------------------------|------|
|                   |                          | Shutdown                                                                   | 8                               | 19                              | nA   |
|                   |                          | Deepstop, no timer,<br>wakeup GPIO, RAM0<br>retained                       | 0.44                            | 0.46                            |      |
|                   |                          | Deepstop, no timer,<br>wakeup GPIO, all<br>RAM retained                    | 0.62                            | 0.64                            |      |
|                   |                          | Deepstop (32 kHz<br>LSI), RAM0 retained                                    | 0.94                            | 1.06                            |      |
|                   |                          | Deepstop (32 kHz<br>LSI), all RAMs<br>retained                             | 1.12                            | 1.24                            |      |
|                   |                          | Deepstop (32 kHz<br>LSE), RAM0 retained                                    | 0.64                            | 0.75                            |      |
| I <sub>CORE</sub> | Core current consumption | Deepstop (32 kHz<br>LSE), all RAM retained                                 | 0.83                            | 0.94                            | μΑ   |
|                   |                          | CPU in Run (64 MHz).<br>Dhrystone, clock<br>source PLL64                   | -                               | 4482                            |      |
|                   |                          | CPU in WFI (64 MHz),<br>all peripherals off,<br>clock source PLL64         | -                               | 2230                            |      |
|                   |                          | CPU in WFI (16 MHz),<br>all peripherals off,<br>clock source direct<br>HSE | -                               | 757                             |      |
|                   |                          | Radio Rx at sensitivity level                                              | -                               | 6700                            |      |
|                   |                          | Radio Tx 0 dBm output power                                                | -                               | 8900                            |      |

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Table 16. Peripheral current consumption at  $V_{DD}$  = 3.3 V, sysclk at 32 MHz, SMPS ON

| Parameter | Test conditions            | Тур. | Unit |
|-----------|----------------------------|------|------|
| ADC       | -                          | 80   |      |
| DMA       | -                          | 39   |      |
| GPIOA     | -                          | 2    |      |
| GPIOB     | -                          | 2    |      |
| I2C1      | -                          | 40   |      |
| I2C2      | -                          | 39   |      |
| 12S2      | Peripheral clock at 32 MHz | 46   |      |
| 12S3      | Peripheral clock at 32 MHz | 47   |      |
| IWDG      | -                          | 11   |      |
| LPUART    | -                          | 52   |      |
| PVD       | -                          | 0.8  |      |
| PKA       | -                          | 50   | μA   |
| RNG       | -                          | 64   |      |
| RTC       | -                          | 14   |      |
| SPI1      | -                          | 35   |      |
| SPI2      | Peripheral clock at 16 MHz | 40   |      |
| SPI3      | Peripheral clock at 16 MHz | 42   |      |
| SysTick   | -                          | 8    |      |
| TIM1      | -                          | 248  |      |
| USART     | -                          | 81   |      |
| SYSCFG    | -                          | 33   |      |
| THSENS    | -                          | 301  |      |
| CRC       | -                          | 9    |      |

# 6.3.3 RF general characteristics

All performance data are referred to a 50  $\boldsymbol{\Omega}$  antenna connector, via reference design.

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Table 17. Bluetooth® LE RF general characteristics

| Symbol             | Parameter                                                                        | Test conditions                                                         | Min. | Тур. | Max.   | Unit   |
|--------------------|----------------------------------------------------------------------------------|-------------------------------------------------------------------------|------|------|--------|--------|
| F <sub>RANGE</sub> | Frequency range <sup>(1)</sup>                                                   | -                                                                       | 2400 | -    | 2483.5 | N41.1- |
| RF <sub>CH</sub>   | RF channel center frequency <sup>(1)</sup>                                       | -                                                                       | 2402 | -    | 2480   | MHz    |
| PLL <sub>RES</sub> | RF channel spacing <sup>(1)</sup>                                                | -                                                                       | -    | 2    | -      | MHz    |
| ΔF                 | Frequency deviation <sup>(1)</sup>                                               | -                                                                       | -    | 250  | -      | kHz    |
| Δf1                | Frequency deviation average <sup>(1)</sup>                                       | -                                                                       | 450  | -    | 550    | kHz    |
| C <sub>Fdev</sub>  | Center frequency deviation <sup>(1)</sup>                                        | During the packet and including both initial frequency offset and drift | -    | -    | ±150   | kHz    |
| Δfa                | Frequency deviation $\Delta f2$ (average) / $\Delta f1$ (average) <sup>(1)</sup> | -                                                                       | 0.80 | -    | -      | -      |
| R <sub>gfsk</sub>  | On-air data rate <sup>(1)</sup>                                                  | -                                                                       | 1    | -    | 2      | Mbps   |
| STacc              | Symbol time accuracy <sup>(1)</sup>                                              | -                                                                       | -    | -    | ±50    | ppm    |
| MOD                | Modulation scheme                                                                | -                                                                       | GFSK |      | <      | -      |
| ВТ                 | Bandwidth-bit period product                                                     | -                                                                       | -    | 0.5  | -      | -      |
| Mindex             | Modulation index <sup>(1)</sup>                                                  | -                                                                       | 0.45 | 0.5  | 0.55   | -      |
| PMAX               | Maximum output                                                                   | At antenna connector, VSMPS = 1.9 V,<br>LDO code                        | -    | +8   | -      | dBm    |
| PMIN               | Minimum output                                                                   | At antenna connector                                                    | -    | -20  | -      | dBm    |
| PRFC               | RF power accuracy                                                                | @ 27 °C                                                                 | -    | ±1.5 | -      | dВ     |
| FRIC               | Ni power accuracy                                                                | All temperatures                                                        | -    | ±2.5 | -      | dB     |

<sup>1.</sup> Tested according to Bluetooth® LE SIG radio frequency physical layer (RF PHY) test suite (not tested in production).

### **6.3.4** RF transmitter characteristics

All performance data are referred to a 50  $\Omega$  antenna connector, via reference design.

Table 18. Bluetooth® LE RF transmitter characteristics at 1 Mbps not coded

| Symbol                    | Parameter                                                        | Test conditions                                                              | Min. | Тур. | Max. | Unit      |
|---------------------------|------------------------------------------------------------------|------------------------------------------------------------------------------|------|------|------|-----------|
| P <sub>BW1M</sub>         | 6 dB bandwidth for modulated carrier                             | Using resolution bandwidth of 100 kHz                                        | 500  | -    | -    | kHz       |
| P <sub>RF1</sub> , 1 Ms/s | In-band emission at ±2 MHz <sup>(1)</sup>                        | Using resolution bandwidth of 100 kHz and average detector                   | -    | -    | -20  | dBm       |
| P <sub>RF2</sub> , 1 Ms/s | In-band emission at $\pm$ [3+n]MHz, where n=0,1,2 <sup>(1)</sup> | Using resolution bandwidth of 100 kHz and average detector                   | -    | -    | -30  | dBm       |
| PS <sub>PUR</sub>         | Spurious emission                                                | Harmonics included. Using resolution bandwidth of 1 MHz and average detector | -    | -    | -41  | dBm       |
| Freq <sub>drift</sub>     | Frequency drift <sup>(1)</sup>                                   | Integration interval #n – integration interval #0, where n=2,3,4k            | -50  | -    | +50  | kHz       |
| IFreq <sub>drift</sub>    | Initial carrier frequency drift <sup>(1)</sup>                   | Integration interval #1 – integration interval #0                            | -23  | -    | +23  | kHz       |
| Int <sub>Freqdrift</sub>  | Intermediate carrier frequency drift <sup>(1)</sup>              | Integration interval #n – integration interval #(n-5), where n=6,7,8k        | -20  | -    | +20  | kHz       |
| Drift Rate max            | Maximum drift rate <sup>(1)</sup>                                | Between any two 10-bit groups separated by 50 µs                             | -20  | -    | +20  | kHz/50 μs |
| Z <sub>RF1</sub>          | Optimum RF load<br>(impedance at RF1 pin)                        | @ 2440 MHz                                                                   | -    | 40   | -    | Ω         |

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1. Tested according to Bluetooth® LE SIG radio frequency physical layer (RF PHY) test suite (not tested in production).

Table 19. Bluetooth® LE RF transmitter characteristics at 2 Mbps not coded

| Symbol                    | Parameter                                                   | Test conditions                                                              | Min. | Тур. | Max. | Unit      |
|---------------------------|-------------------------------------------------------------|------------------------------------------------------------------------------|------|------|------|-----------|
| P <sub>BW1M</sub>         | 6 dB bandwidth for modulated carrier                        | Using resolution bandwidth of 100 kHz                                        | 670  | -    | -    | kHz       |
| P <sub>RF1</sub> , 2 Ms/s | In-band emission at ±4 MHz <sup>(1)</sup>                   | Using resolution bandwidth of 100 kHz and average detector                   | -    | -    | -20  | dBm       |
| P <sub>RF2</sub> , 2 Ms/s | In-band emission at±5 MHz <sup>(1)</sup>                    | Using resolution bandwidth of 100 kHz and average detector                   | -    | -    | -20  | dBm       |
| P <sub>RF3</sub> , 2 Ms/s | In-band emission at ±[6+n]MHz, where n=0,1,2 <sup>(1)</sup> | Using resolution bandwidth of 100 kHz and average detector                   | -    | -    | -30  | dBm       |
| P <sub>SPUR</sub>         | Spurious emission                                           | Harmonics included. Using resolution bandwidth of 1 MHz and average detector | -    | -    | -41  | dBm       |
| Freq <sub>drift</sub>     | Frequency drift <sup>(1)</sup>                              | Integration interval #n – integration interval #0, where n=2,3,4k            | -50  | -    | +50  | kHz       |
| IFreq <sub>drift</sub>    | Initial carrier frequency drift <sup>(1)</sup>              | Integration interval #1 – integration interval #0                            | -23  | -    | +23  | kHz       |
| IntFreq <sub>drift</sub>  | Intermediate carrier frequency drift <sup>(1)</sup>         | Integration interval #n – integration interval #(n-5), where n=6,7,8k        | -20  | -    | +20  | kHz       |
| DriftRate <sub>max</sub>  | Maximum drift rate <sup>(1)</sup>                           | Between any two 20-bit groups separated by 50 µs                             | -20  | -    | +20  | kHz/50 μs |
| Z <sub>RF1</sub>          | Optimum RF load (impedance at RF1 pin)                      | @ 2440 MHz                                                                   | -    | 40   | -    | Ω         |

<sup>1.</sup> Tested according to Bluetooth® LE SIG radio frequency physical layer (RF PHY) test suite (not tested in production).

Table 20. Bluetooth® LE RF transmitter characteristics at 1 Mbps LE coded (S = 8)

| Symbol                     | Parameter                                                    | Test conditions                                                              | Min.  | Тур. | Max.  | Unit      |
|----------------------------|--------------------------------------------------------------|------------------------------------------------------------------------------|-------|------|-------|-----------|
| P <sub>BW</sub>            | 6 dB bandwidth for modulated carrier                         | Using resolution bandwidth of 100 kHz                                        | 500   | _    | _     | kHz       |
| P <sub>RF1, LE</sub> coded | In-band emission at ±2 MHz <sup>(1)</sup>                    | Using resolution bandwidth of 100 kHz and average detector                   | -     | -    | -20   | dBm       |
| P <sub>RF2, LE</sub> coded | In-band emission at ±[3+n] MHz, where n=0,1,2 <sup>(1)</sup> | Using resolution bandwidth of 100 kHz and average detector                   | -     | -    | -30   | dBm       |
| PS <sub>PUR</sub>          | Spurious emission                                            | Harmonics included. Using resolution bandwidth of 1 MHz and average detector | -     | -    | -41   | dBm       |
| Freq <sub>drift</sub>      | Frequency drift <sup>(1)</sup>                               | Integration interval #n – integration interval #0, where n=1,2,3k            | -50   | -    | +50   | kHz       |
| IFreq <sub>drift</sub>     | Initial carrier frequency drift <sup>(1)</sup>               | Integration interval #3 – integration interval #0                            | -19.2 | _    | +19.2 | kHz       |
| IntFreq <sub>drift</sub>   | Intermediate carrier frequency ${\rm drift}^{(1)}$           | Integration interval #n – integration interval #(n-3), where n=7,8,9k        | -19.2 | _    | +19.2 | kHz       |
| DriftRate <sub>max</sub>   | Maximum drift rate <sup>(1)</sup>                            | Between any two 16-bit groups separated by 48 µs                             | -19.2 | -    | +19.2 | kHz/48 μs |
| Z <sub>RF1</sub>           | Optimum RF load                                              | @ 2440 MHz                                                                   | _     | 40   | _     | Ω         |
|                            | (Impedance at RF1 pin)                                       |                                                                              |       |      |       |           |

<sup>1.</sup> Tested according to Bluetooth® LE SIG radio frequency physical layer (RF PHY) test suite (not tested in production).

#### 6.3.5 RF receiver characteristics

All performance data are referred to a 50  $\Omega$  antenna connector, via reference design.

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Table 21. Bluetooth® LE RF receiver characteristics at 1 Msym/s uncoded

| Symbol                     | Parameter                                                                                 | Test conditions                                                     | Min.    | Тур. | Max. | Unit |
|----------------------------|-------------------------------------------------------------------------------------------|---------------------------------------------------------------------|---------|------|------|------|
| RX <sub>SENS</sub>         | Sensitivity                                                                               | PER < 30.8%                                                         | -       | -97  | -    | dBm  |
| P <sub>SAT</sub>           | Saturation                                                                                | PER < 30.8%                                                         | -       | 8    | -    | dBm  |
| Z <sub>RF1</sub>           | Optimum RF source (impedance at RF1 pin)                                                  | @ 2440 MHz                                                          |         | 40   | -    | Ω    |
|                            | RF selectivity with Bluetooth® L                                                          | E equal modulation on interfering signa                             | I       |      | I    |      |
| C/I <sub>CO-channel</sub>  | Co-channel interference $f_{RX} = f_{interference}$                                       | Wanted signal = -67 dBm, PER < 30.8%                                | -       | 8    | -    | dBc  |
| C/I <sub>1 MHz</sub>       | Adjacent interference<br>f <sub>interference</sub> = f <sub>RX</sub> ± 1 MHz              | Wanted signal = -67 dBm, PER < 30.8%                                | -       | -1   | -    | dBc  |
| C/I <sub>2 MHz</sub>       | Adjacent interference<br>f <sub>interference</sub> = f <sub>RX</sub> ± 2 MHz              | Wanted signal = -67 dBm, PER < 30.8%                                | -       | -35  | -    | dBc  |
| C/I <sub>3 MHz</sub>       | Adjacent interference<br>$f_{interference} = f_{RX} \pm (3+n) \text{ MHz}$<br>[n = 0,1,2] | Wanted signal = -67 dBm, PER < 30.8%                                | -       | -47  | -    | dBc  |
| C/I <sub>Image</sub>       | Image frequency interference  finterference = fimage                                      | Wanted signal = -67 dBm, PER < 30.8%                                | -       | -25  | -    | dBc  |
| C/I                        | Adjacent channel-to-image frequency                                                       | Wanted signal= -67 dBm, PER < 30.8%                                 |         | -25  | _    | dDa  |
| C/I <sub>Image±1 MHz</sub> | f <sub>interference</sub> = f <sub>image</sub> ± 1 MHz                                    |                                                                     |         | -25  | -    | dBc  |
|                            | Out of band block                                                                         | ing (interfering signal CW)                                         |         |      |      |      |
| C/I <sub>Block</sub>       | Interfering signal frequency 30 MHz – 2000 MHz                                            | Wanted signal = -67 dBm, PER < 30.8%, measurement resolution 10 MHz | -       | 5    | -    | dB   |
| C/I <sub>Block</sub>       | Interfering signal frequency 2003 MHz – 2399 MHz                                          | Wanted signal = -67 dBm, PER < 30.8%, measurement resolution 3 MHz  | -       | -5   | -    | dB   |
| C/I <sub>Block</sub>       | Interfering signal frequency 2484 MHz – 2997 MHz                                          | Wanted signal = -67 dBm, PER < 30.8%, measurement resolution 3 MHz  | -       | -5   | -    | dB   |
| C/I <sub>Block</sub>       | Interfering signal frequency 3000 MHz – 12.75 GHz                                         | Wanted signal = -67 dBm, PER < 30.8%, measurement resolution 25 MHz | -       | 10   | -    | dB   |
|                            | Intermodulation characteristics (CW sig                                                   | gnal at f <sub>1</sub> , Bluetooth <sup>®</sup> LE interfering sign | al at f | 2)   |      |      |
| P_IM(3)                    | Input power of IM interferer at 3 and 6 MHz distance from the wanted signal               | Wanted signal = -64 dBm, PER < 30.8%                                | -       | -27  | -    | dBm  |
| P_IM(-3)                   | Input power of IM interferer at -3 and -6 MHz distance from the wanted signal             | Wanted signal = -64 dBm, PER < 30.8%                                | -       | -40  | -    | dBm  |
| P_IM(4)                    | Input power of IM interferer at ±4 and ±8 MHz distance from the wanted signal             | Wanted signal= -64 dBm, PER < 30.8%                                 | -       | -32  | -    | dBm  |
| P_IM(5)                    | Input power of IM interferer at ±5 and ±10 MHz distance from the wanted signal            | Wanted signal = -64 dBm, PER < 30.8%                                | -       | -32  | -    | dBm  |

Table 22. Bluetooth® LE RF receiver characteristics at 2 Msym/s uncoded

| Symbol             | Parameter                                   | Test conditions | Min. | Тур. | Max. | Unit |
|--------------------|---------------------------------------------|-----------------|------|------|------|------|
| RX <sub>SENS</sub> | Sensitivity                                 | PER < 30.8%     | -    | -94  | -    | dBm  |
| P <sub>SAT</sub>   | Saturation                                  | PER < 30.8%     | -    | 8    | -    | dBm  |
| Z <sub>RF1</sub>   | Optimum RF source<br>(impedance at RF1 pin) | @ 2440 MHz      | -    | 40   | -    | Ω    |

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| Symbol                     | Parameter                                                                                             | Test conditions                                                    | Min.    | Тур. | Max. | Unit |
|----------------------------|-------------------------------------------------------------------------------------------------------|--------------------------------------------------------------------|---------|------|------|------|
|                            | RF selectivity with Bluetooth <sup>®</sup> LE                                                         | equal modulation on interfering signa                              |         |      |      |      |
| C/I <sub>CO-channel</sub>  | Co-channel interference $f_{RX} = f_{interference}$                                                   | Wanted signal= -67 dBm, PER < 30.8%                                | -       | 8    | _    | dBc  |
| C/I <sub>2 MHz</sub>       | Adjacent interference<br>$f_{interference} = f_{RX} \pm 2 \text{ MHz}$                                | Wanted signal = -67 dBm, PER < 30.8%                               | -       | -14  | -    | dBc  |
| C/I <sub>4 MHz</sub>       | Adjacent interference<br>$f_{interference} = f_{RX} \pm 4 \text{ MHz}$                                | Wanted signal = -67 dBm, PER < 30.8%                               | -       | -41  | -    | dBc  |
| C/I <sub>6 MHz</sub>       | Adjacent interference<br>$f_{interference} = f_{RX} \pm (6+2n) \text{ MHz}$<br>[n = 0,1,2]            | Wanted signal = -67 dBm, PER < 30.8%                               | -       | -45  | -    | dBc  |
| C/I <sub>Image</sub>       | Image frequency interference<br>f <sub>interference</sub> = f <sub>image-2M</sub>                     | Wanted signal = -67 dBm, PER < 30.8%                               | _       | -25  | _    | dBc  |
| C/I <sub>Image±1 MHz</sub> | Adjacent channel-to-image frequency $f_{\text{interference}} = f_{\text{image-2M}} \pm 2 \text{ MHz}$ | Wanted signal= -67 dBm, PER < 30.8%                                | -       | -14  | -    | dBc  |
|                            | Out of band blocki                                                                                    | ng (interfering signal CW)                                         |         |      |      |      |
| C/I <sub>Block</sub>       | Interfering signal frequency 30 MHz – 2000 MHz                                                        | Wanted signal= -67 dBm, PER < 30.8%, measurement resolution 10 MHz | -       | 5    | -    | dB   |
| C/I <sub>Block</sub>       | Interfering signal frequency 2003 MHz – 2399 MHz                                                      | Wanted signal= -67 dBm, PER < 30.8%, measurement resolution 3 MHz  | -       | -5   | -    | dB   |
| C/I <sub>Block</sub>       | Interfering signal frequency 2484 MHz – 2997 MHz                                                      | Wanted signal= -67 dBm, PER < 30.8%, measurement resolution 3 MHz  | -       | -5   | -    | dB   |
| C/I <sub>Block</sub>       | Interfering signal frequency 3000 MHz – 12.75 GHz                                                     | Wanted signal= -67 dBm, PER < 30.8%, measurement resolution 25 MHz | -       | 10   | -    | dB   |
|                            | Intermodulation characteristics (CW sig                                                               | nal at f <sub>1</sub> , Bluetooth <sup>®</sup> LE interfering sign | al at f | 2)   |      |      |
| P_IM(6)                    | Input power of IM interferer at 6 and 12 MHz distance from the wanted signal                          | Wanted signal= -64 dBm, PER < 30.8%                                | -       | -27  | -    | dBm  |
| P_IM(-6)                   | Input power of IM interferer at -6 and -12 MHz distance from the wanted signal                        | Wanted signal= -64 dBm, PER < 30.8%                                | -       | -30  | -    | dBm  |
| P_IM(8)                    | Input power of IM interferer at ±8 and ±16 MHz distance from the wanted signal                        | Wanted signal= -64 dBm, PER < 30.8%                                | -       | -30  | -    | dBm  |
| P_IM(10)                   | Input power of IM interferer at ±10 and ±20 MHz distance from the wanted signal                       | Wanted signal= -64 dBm, PER < 30.8%                                | -       | -28  | _    | dBm  |

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Table 23. Bluetooth® LE RF receiver characteristics at 1 Msym/s LE coded (S=2)

| Symbol                                                                   | Parameter                                                                            | Test conditions                      | Min. | Тур. | Max. | Unit |  |  |  |  |
|--------------------------------------------------------------------------|--------------------------------------------------------------------------------------|--------------------------------------|------|------|------|------|--|--|--|--|
| RX <sub>SENS</sub>                                                       | Sensitivity                                                                          | PER < 30.8%                          |      | -100 | -    | dBm  |  |  |  |  |
| P <sub>SAT</sub>                                                         | Saturation                                                                           | PER < 30.8%                          | _    | 8    | -    | dBm  |  |  |  |  |
| Z <sub>RF1</sub>                                                         | Optimum RF source<br>(impedance at RF1 pin)                                          | @ 2440 MHz                           |      | 40   | -    | Ω    |  |  |  |  |
| RF selectivity with Bluetooth® LE equal modulation on interfering signal |                                                                                      |                                      |      |      |      |      |  |  |  |  |
| C/I <sub>CO</sub> -channel                                               | Co-channel interference $f_{RX} = f_{interference}$                                  | Wanted signal = -79 dBm, PER < 30.8% |      | 2    | -    | dBc  |  |  |  |  |
| C/I <sub>1 MHz</sub>                                                     | Adjacent interference<br>f <sub>interference</sub> = f <sub>RX</sub> ± 1 MHz         | Wanted signal = -79 dBm, PER < 30.8% |      | -5   | -    | dBc  |  |  |  |  |
| C/I <sub>2 MHz</sub>                                                     | Adjacent interference<br>f <sub>interference</sub> = f <sub>RX</sub> ± 2 MHz         | Wanted signal = -79 dBm, PER < 30.8% |      | -38  | -    | dBc  |  |  |  |  |
| C/I <sub>3 MHz</sub>                                                     | Adjacent interference $f_{interference} = f_{RX} \pm (3+n) \text{ MHz}$ [n = 0,1,2]  | Wanted signal = -79 dBm, PER < 30.8% | _    | -50  | -    | dBc  |  |  |  |  |
| C/I <sub>Image</sub>                                                     | Image frequency interference $f_{interference} = f_{image}$                          | Wanted signal = -79 dBm, PER < 30.8% |      | -30  | -    | dBc  |  |  |  |  |
| C/I <sub>Image±1</sub> MHz                                               | Adjacent channel-to-image frequency $f_{interference} = f_{image} \pm 1 \text{ MHz}$ | Wanted signal = -79 dBm, PER < 30.8% |      | -34  | -    | dBc  |  |  |  |  |

Table 24. Bluetooth® LE RF receiver characteristics at 1 Msym/s LE coded (S = 8)

| Symbol                       | Parameter                                                                                   | Test conditions                      | Min. | Тур. | Max. | Unit |  |  |  |  |
|------------------------------|---------------------------------------------------------------------------------------------|--------------------------------------|------|------|------|------|--|--|--|--|
| RX <sub>SENS</sub>           | Sensitivity                                                                                 | PER < 30.8%                          |      | -104 | -    | dBm  |  |  |  |  |
| P <sub>SAT</sub>             | Saturation                                                                                  | PER < 30.8%                          | _    | 8    | -    | dBm  |  |  |  |  |
| Z <sub>RF1</sub>             | Optimum RF source<br>(impedance at RF1 pin)                                                 | @ 2440 MHz                           |      | 40   | -    | Ω    |  |  |  |  |
|                              | RF selectivity with Bluetooth® LE equal modulation on interfering signal                    |                                      |      |      |      |      |  |  |  |  |
| C/I <sub>CO-channel</sub>    | Co-channel interference $f_{RX} = f_{interference}$ Wanted signal = -79 dBm, PER < 30.8%    |                                      |      | 1    | -    | dBc  |  |  |  |  |
| C/I <sub>1 MHz</sub>         | Adjacent interference<br>f <sub>interference</sub> = f <sub>RX</sub> ± 1 MHz                | Wanted signal = -79 dBm, PER < 30.8% |      | -4   | -    | dBc  |  |  |  |  |
| C/I <sub>2 MHz</sub>         | Adjacent interference<br>f <sub>interference</sub> = f <sub>RX</sub> ± 2 MHz                | Wanted signal = -79 dBm, PER < 30.8% |      | -39  | -    | dBc  |  |  |  |  |
| C/I <sub>3 MHz</sub>         | Adjacent interference $f_{interference} = f_{RX} \pm (3+n) \text{ MHz}$ $[n = 0,1,2]$       | Wanted signal = -79 dBm, PER < 30.8% | -    | -53  | -    | dBc  |  |  |  |  |
| C/I <sub>Image</sub>         | Image frequency interference  f <sub>interference</sub> = f <sub>image</sub>                | Wanted signal = -79 dBm, PER < 30.8% |      | -33  | -    | dBc  |  |  |  |  |
| C/I <sub>Image</sub> ± 1 MHz | Adjacent channel-to-image frequency  f <sub>interference</sub> = f <sub>image</sub> ± 1 MHz | Wanted signal = -79 dBm, PER < 30.8% |      | -32  | -    | dBc  |  |  |  |  |

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### 6.3.6 Embedded reset and power control block characteristics

Table 25. Embedded reset and power control block characteristics

| Symbol    | Parameter                                 | Test conditions                                      | Min. | Тур. | Max. | Unit |
|-----------|-------------------------------------------|------------------------------------------------------|------|------|------|------|
| TRSTTEMPO | Reset temporization after PDR is detected | VDD rising                                           | -    | -    | 500  | us   |
| VPDR      | Power-down reset threshold                | -                                                    | -    | 1.63 | -    |      |
| VPVD0     | PVD0 threshold                            | PVD0 threshold at the falling edge of VDDIO          | -    | 2.05 | -    |      |
| VPVD1     | PVD1 threshold                            | PVD1 threshold at the falling edge of VDDIO          | -    | 2.21 | -    |      |
| VPVD2     | PVD2 threshold                            | PVD2 threshold at the falling edge of VDDIO          | -    | 2.36 | -    |      |
| VPVD3     | PVD3 threshold                            | PVD3 threshold at the falling edge of VDDIO          | -    | 2.53 | -    | V    |
| VPVD4     | PVD4 threshold                            | PVD4 threshold at the falling edge of VDDIO          | -    | 2.64 | -    |      |
| VPVD5     | PVD5 threshold                            | PVD5 threshold at the falling edge of VDDIO          | -    | 2.82 | -    |      |
| VPVD6     | PVD6 threshold                            | PVD6 threshold at the falling edge of VDDIO          | -    | 2.91 | -    |      |
| VPVD7     | PVD threshold for VIN_PVD                 | PVD7 threshold (VBGP) at the falling edge of VIN_PVD | -    | 1.2  | -    |      |

## 6.3.7 Supply current characteristics

The current consumption is a function of several parameters and factors such as: the operating voltage, ambient temperature, I/O pin loading, device software configuration, operating frequencies, I/O pin switching rate, program location in memory and executed binary code.

The MCU is put under the following conditions:

- All I/O pins are in analog input mode
- All peripherals are disabled except when explicitly mentioned
- The flash memory access time is adjusted with the minimum wait state number
- When the peripherals are enabled f<sub>PCLK</sub> = f<sub>HCLK</sub>

Table 26. Current consumption

| Symbol                      | Parameter                                 | Conditions                                             |      | Unit  |        |       |
|-----------------------------|-------------------------------------------|--------------------------------------------------------|------|-------|--------|-------|
| Зушьы                       | raiailletei                               | Conditions                                             | 25°C | 85 °C | 105 °C | Ullit |
| I <sub>DD</sub> (Run)       | Supply current in Run mode                | f <sub>HCLK</sub> = 64 MHz<br>All peripherals disabled | 2.40 | 2.49  | 2.54   |       |
|                             |                                           | f <sub>HCLK</sub> = 32 MHz All peripherals disabled    | 1.98 | 2.03  | 2.08   | mA    |
|                             |                                           | f <sub>HCLK</sub> = 16 MHz<br>All peripherals disabled | 1.62 | 1.67  | 1.71   |       |
|                             | Supply current in Deepstop <sup>(1)</sup> | Timer OFF                                              | 0.65 | 6.73  | 15.73  | μA    |
|                             |                                           | Timer source LSI                                       | 1.25 | 7.41  | 16.46  |       |
| I <sub>DD</sub> (Deepstop)  |                                           | Timer source LSI<br>RTC ON                             | 1.30 | 7.56  | 16.70  |       |
| . <sub>DD</sub> (2 copolop) |                                           | Timer source LSI<br>IWDG ON                            | 1.27 | 7.47  | 16.55  |       |
|                             |                                           | Timer source LSI<br>RTC and IWDG ON                    | 1.33 | 7.61  | 16.79  |       |

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| Symbol                     | Parameter                                 | Conditions -                        |      | Unit  |        |       |
|----------------------------|-------------------------------------------|-------------------------------------|------|-------|--------|-------|
| Зушьог                     |                                           |                                     | 25°C | 85 °C | 105 °C | Oilit |
|                            | Supply current in Deepstop <sup>(1)</sup> | Timer source LSE                    | 1.00 | 7.16  | 16.22  |       |
| I <sub>DD</sub> (Deepstop) |                                           | Timer source LSE<br>RTC ON          | 1.06 | 7.31  | 16.45  |       |
|                            |                                           | Timer source LSE IWDG ON            | 1.02 | 7.22  | 16.30  | μА    |
|                            |                                           | Timer source LSE<br>RTC and IWDG ON | 1.07 | 7.36  | 16.54  |       |
| I <sub>DD</sub> (Shutdown) | Supply current in Shutdown                | -                                   | 0.02 | 0.46  | 1.36   |       |
| I <sub>DD</sub> (RST)      | Current under reset condition             | -                                   | 1.34 | 1.45  | 1.55   | mA    |

<sup>1.</sup> The current consumption in Deepstop is measured considering the entire SRAM retained.

#### 6.3.8 Wakeup time from low power modes

The wakeup times reported are the latency between the event and the execution of the instruction. The device goes to low-power mode after WFI (wait for interrupt) instructions.

Table 27. Low power mode wakeup timing

| Symbol                  | Parameter                                  | Conditions                                | Тур. | Unit |
|-------------------------|--------------------------------------------|-------------------------------------------|------|------|
| T <sub>WUDEEPSTOP</sub> | Wakeup time from Deepstop mode to Run mode | Wakeup from GPIO VDD = 3.3 V flash memory | 110  | μs   |

#### 6.3.9 External clock source characteristics

#### 6.3.9.1 High speed crystal requirements

The high speed external oscillator must be supplied with an external 32 MHz crystal that is specified for a 6 to 8 pF loading capacitor. The STM32WB0xxC includes internal programmable capacitances that can be used to tune the crystal frequency to compensate the PCB parasitic one. These internal load capacitors are made by a fixed one, in parallel with a 6-bit binary weighted capacitor bank. Thanks to the low CL step size (LSB is typically 0.07 pF), very fine crystal tuning is possible. With a typical XTAL sensitivity of -14 ppm/pF, it is possible to trim a 32 MHz crystal, with a resolution of 1 ppm.

The requirements for the external 32 MHz crystal are reported in the table below.

Table 28. HSE crystal requirements

| Symbol           | Parameter                                 | Conditions                                                                                                            | Min.  | Тур.             | Max.               | Unit |
|------------------|-------------------------------------------|-----------------------------------------------------------------------------------------------------------------------|-------|------------------|--------------------|------|
| f <sub>NOM</sub> | Oscillator frequency                      | -                                                                                                                     | -     | 32               | -                  | MHz  |
| f <sub>TOL</sub> | Frequency tolerance                       | Includes initial accuracy, stability over temperature, aging, and frequency pulling due to incorrect load capacitance | -     | -                | ±50                | ppm  |
| ESR              | Equivalent series resistance              | -                                                                                                                     | -     | -                | 100                | Ω    |
| P <sub>D</sub>   | Drive level                               | -                                                                                                                     | -     | -                | 100                | μW   |
| CL               | HSE crystal load capacitance              | 27°C, typical corner<br>GMCONF = 3                                                                                    | 5 (1) | 7 <sup>(2)</sup> | 9.2 <sup>(3)</sup> | pF   |
| CLstep           | HSE crystal load capacitance<br>LSB value | 27 °C,<br>GMCONF = 3<br>XOTUNE code between 32 and 33                                                                 | -     | 0.07             | -                  | pF   |

<sup>1.</sup> XOTUNE programmed at minimum code = 0

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<sup>2.</sup> XOTUNE programmed at center code = 32



#### 3. XOTUNE programmed at maximum code = 63

### 6.3.9.2 Low speed crystal requirements

A low speed clock can be supplied with an external 32.768 kHz crystal oscillator. Requirements for the external 32.768 kHz crystal are reported in the table below.

Table 29. LSE crystal requirements

| Symbol                | Parameter                               | Conditions                                     | Min. | Тур.   | Max. | Unit |
|-----------------------|-----------------------------------------|------------------------------------------------|------|--------|------|------|
| f <sub>NOM</sub>      | Nominal frequency                       | -                                              | -    | 32.768 | -    | kHz  |
| ESR                   | Equivalent series resistance            | -                                              | -    | -      | 90   | kΩ   |
| P <sub>D</sub>        | Drive level                             | -                                              | -    | -      | 0.1  | μW   |
|                       |                                         | LSEDRV[1:0] = 00  Low drive capability         | -    | -      | 0.50 |      |
|                       | Maximum oritical or total or            | LSEDRV[1:0] = 01  Medium low drive capability  | -    | -      | 0.75 |      |
| G <sub>mcritmax</sub> | Maximum critical crystal g <sub>m</sub> | LSEDRV[1:0] = 10  Medium high drive capability | -    | -      | 1.70 | μA/V |
|                       |                                         | LSEDRV[1:0] = 11 High drive capability         | -    | -      | 2.70 |      |

#### 6.3.10 Internal clock source characteristics

#### 6.3.10.1 High speed ring oscillator characteristics

Table 30. HSI oscillator characteristics

| Symbol           | Parameter         | Conditions | Min. | Тур. | Max. | Unit |
|------------------|-------------------|------------|------|------|------|------|
| f <sub>NOM</sub> | Nominal frequency | -          | -    | 64   | -    | MHz  |

### 6.3.10.2 Low speed ring oscillator characteristics

Table 31. LSI oscillator characteristics

| Symbol                            | Parameter                        | Conditions         | Min. | Тур. | Max. | Unit   |
|-----------------------------------|----------------------------------|--------------------|------|------|------|--------|
| f <sub>NOM</sub>                  | Nominal frequency                | -                  | -    | 33   | -    | kHz    |
| $\Delta F_{RO}_{\Delta T}/F_{RO}$ | Frequency spread vs. temperature | Standard deviation | -    | 140  | -    | ppm/°C |

#### 6.3.11 PLL characteristics

Characteristics measured over recommended operating conditions unless otherwise specified.

**Table 32. PLL characteristics** 

| Symbol              | Parameter              | Conditions                    | Min. | Тур. | Max. | Unit    |
|---------------------|------------------------|-------------------------------|------|------|------|---------|
| DN                  | DE                     | At ±1 MHz offset from carrier |      | -110 |      | dBc/Hz  |
| PN <sub>SYNTH</sub> | RF carrier phase noise | (measured at 2.4 GHz)         | _    | -110 | -    | UBC/FIZ |

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| Symbol                   | Parameter              | Conditions                            |   | Тур. | Max. | Unit    |
|--------------------------|------------------------|---------------------------------------|---|------|------|---------|
|                          |                        | At 2.4 GHz ±3 MHz offset from carrier |   | -114 | _    | dBc/Hz  |
|                          |                        | (measured at 2.4 GHz)                 | - | -114 | -    | UBC/FIZ |
| PN <sub>SYNTH</sub>      | RF carrier phase noise | At 2.4 GHz±6 MHz offset from carrier  |   | -128 | -    | dBc/Hz  |
|                          |                        | (measured at 2.4 GHz)                 | - | -120 |      | UBC/HZ  |
|                          |                        | At ±25 MHz offset from carrier        | - | -135 | -    | dBc/Hz  |
| LOCK <sub>TIMETX</sub>   | PLL lock time to TX    | With calibration @2.5 ppm             | - | 150  | -    | μs      |
| LOCK <sub>TIMERX</sub>   | PLL lock time to RX    | With calibration @2.5 ppm             | - | 110  | -    | μs      |
| LOCK <sub>TIMERXTX</sub> | PLL lock time RX to TX | Without calibration @2.5 ppm          | - | 47   | -    | μs      |
| LOCK <sub>TIMETXRX</sub> | PLL lock time TX to RX | Without calibration @2.5 ppm          | - | 32   | -    | μs      |

# 6.3.12 Flash memory characteristics

The characteristics below are specified by design - not tested in production.

Table 33. Flash memory characteristics

| Symbol                  | Parameter                                            | Test conditions | Тур. | Max. | Unit |
|-------------------------|------------------------------------------------------|-----------------|------|------|------|
| t <sub>prog</sub>       | 32-bit programming time                              | -               | 20   | 40   |      |
| t <sub>prog_burst</sub> | 4x32-bit burst programming time                      | -               | 4x20 | 4x40 | μs   |
| t <sub>ERASE</sub>      | Page (2 Kbytes) erase time                           | -               | 20   | 40   |      |
| t <sub>ME</sub>         | Mass erase time                                      | -               | 20   | 40   | ms   |
|                         |                                                      | Write mode      | 3    | -    |      |
| I <sub>DD</sub>         | Average consumption from $V_{\mbox{\scriptsize DD}}$ | Erase mode      | 3    | -    | mA   |
|                         |                                                      | Mass erase      | 5    | -    |      |

Table 34. Flash memory endurance and data retention

| Symbol           | Parameter      | Test conditions                 | Min. | Unit    |
|------------------|----------------|---------------------------------|------|---------|
| N <sub>END</sub> | Endurance      | T <sub>A</sub> = -40 to +105 °C | 10   | kcycles |
| t <sub>RET</sub> | Data retention | T <sub>A</sub> = 105 °C         | 10   | Years   |

### 6.3.13 Electrostatic discharge (ESD)

Electrostatic discharges (a positive then a negative pulse separated by 1 second) are applied to the pins of each sample according to each pin combination. The sample size depends on the number of supply pins in the device (3 parts x (n + 1) supply pins). This test conforms to the ANSI/JEDEC standard.

Table 35. ESD absolute maximum ratings

| Symbo                | Parameter                                             | Conditions                                 | Class | Max. <sup>(1)</sup> | Unit |
|----------------------|-------------------------------------------------------|--------------------------------------------|-------|---------------------|------|
| V <sub>ESD(HBI</sub> | Electrostatic discharge voltage (human body model)    | Conforming to ANSI/ESDA/JEDEC JS-001       | 2     | 2000                | V    |
| V <sub>ESD(CBI</sub> | Electrostatic discharge voltage (charge device model) | Conforming to ANSI/ESDA/STM5.3.1<br>JS-002 | C2a   | 500                 | V    |

1. Guaranteed by design.

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#### 6.3.14 I/O port characteristics

Unless otherwise specified, the parameters given in the tables below are derived from tests performed under the conditions summarized in General operating conditions. All I/Os are designed as CMOS-compliant.

The characteristics below are guaranteed by characterization.

Table 36, I/O static characteristics

| Symbol           | Parameter                    | Conditions                                          | Min.      | Тур. | Max.      | Unit |
|------------------|------------------------------|-----------------------------------------------------|-----------|------|-----------|------|
| V <sub>IL</sub>  | I/O input low level voltage  | 1.62 V < VDD < 3.6 V                                | -         | -    | 0.3 x VDD | V    |
| V <sub>IH</sub>  | I/O input high level voltage | 1.02 V < VDD < 3.6 V                                | 0.7 x VDD | -    | -         | V    |
|                  |                              | 0 <= VIN <= Max(VDDx) <sup>(1)</sup>                | -         | -    | +/-100    |      |
| I <sub>lkg</sub> | Input leakage current        | $Max(VDDx)^{(1)} \le VIN \le Max(VDDx)^{(1)} + 1 V$ | -         | -    | 650       | nA   |
|                  |                              | Max(VDDx) <sup>(1)</sup> + 1 V < VIN <= 5.5 V       | -         | -    | 200       |      |
| R <sub>PU</sub>  | Pull-up resistor             | VIN = GND                                           | 25        | 40   | 55        | kΩ   |
| R <sub>PD</sub>  | Pull-down resistor           | VIN = VDD                                           | 25        | 40   | 55        | K\$2 |
| C <sub>IO</sub>  | I/O pin capacitance          | -                                                   | -         | 5    | -         | pF   |

<sup>1.</sup> Max(VDDx) is the maximum value among all the I/O supplies.

All I/Os are CMOS-compliant (no software configuration required).

GPIOs (general purpose input/outputs) can sink or source up to  $\pm 8$  mA and sink or source up to  $\pm 20$  mA (with a relaxed  $V_{OL}$  /  $V_{OH}$ ).

In the user application, the number of I/O pins that can drive current must be limited to respect the absolute maximum rating specified.

- The sum of currents sourced by all I/Os on VDD, plus the maximum consumption of MCU sourced on VDD, cannot exceed the absolute maximum rating ΣIVDD
- The sum of currents sunk by all I/Os on VSS, plus the maximum consumption of the MCU sunk on GND, cannot exceed the absolute maximum rating ΣIVGND

The characteristics below are guaranteed by characterization.

Table 37. Output voltage characteristics

| Symbol          | Parameter                             | Conditions                                        | Min.     | Max. | Unit |
|-----------------|---------------------------------------|---------------------------------------------------|----------|------|------|
| V <sub>OL</sub> | Output low level voltage for I/O pin  | CMOS port <sup>(1)</sup>  IIO  = 8 mA VDD ≥ 2.7 V | -        | 0.4  |      |
| V <sub>OH</sub> | Output high level voltage for I/O pin | CINIOS PORTA (IIIO) – 8 IIIA VDD 2 2.7 V          | VDD -0.4 | -    |      |
| V <sub>OL</sub> | Output low level voltage for I/O pin  | IIO  = 20 mA VDD ≥ 2.7 V                          | -        | 1.3  | V    |
| V <sub>OH</sub> | Output high level voltage for I/O pin | 110  - 20 11A VDD 2 2.7 V                         | VDD -1.3 | -    | V    |
| V <sub>OL</sub> | Output low level voltage for I/O pin  | IIO  = 4 mA VDD ≥ 1.62 V                          | -        | 0.4  |      |
| V <sub>OH</sub> | Output high level voltage for I/O pin | 110  - 4 111A VDD 2 1.02 V                        | VDD-0.45 | -    |      |

<sup>1.</sup> CMOS outputs are compatible with JEDEC standards JESD36 and JESD52.

#### 6.3.15 RSTN pin characteristics

The RSTN pin input driver uses CMOS technology. It is connected to a permanent pull-up resistor, RPU.

Unless otherwise specified, the parameters given in the table below are derived from tests performed under the ambient temperature and supply voltage conditions summarized in General operating conditions.

The characteristics below are specified by design - not tested in production.

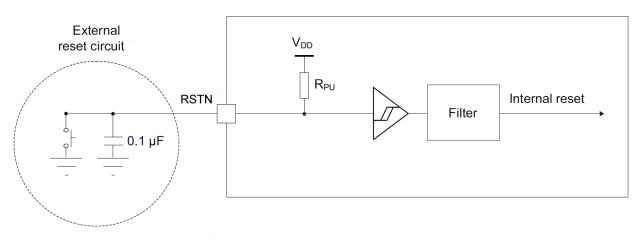
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| Table 38. | <b>RSTN</b> | pin c | haract | eristics |
|-----------|-------------|-------|--------|----------|
|-----------|-------------|-------|--------|----------|

| Symbol                 | Parameter                               | Test conditions | Min.      | Тур. | Max.      | Unit. |
|------------------------|-----------------------------------------|-----------------|-----------|------|-----------|-------|
| V <sub>IL(RSTN)</sub>  | RSTN input low level voltage            | -               | -         | -    | 0.3 x VDD | V     |
| V <sub>IH(RSTN)</sub>  | RSTN input high level voltage           | -               | 0.7 x VDD | -    | -         | V     |
| V <sub>hys(RSTN)</sub> | RSTN Schmitt trigger voltage hysteresis | -               | -         | 200  | -         | mV    |
| RPU                    | Weak pull-up equivalent resistor        | VIN=GND         | 25        | 40   | 55        | kΩ    |

Figure 15. Recommended RSTN pin protection



r) The user matters. On that the levels whe beginning parasition below the VII. (RSTN) max level specified in the by the user must ensure that the levels on the RSTN pin can go below the VII. (RSTN) max level specified in the byte otherwise the reset will not be taken into account by the device.

Note: The external reset circuit protects the device against parasitic resets.

The user must ensure that the level on the RSTN pin can go below the  $V_{\rm IL}(RSTN)$  max. level specified in the table, otherwise the reset is not considered by the device. The external capacitor on RSTN must be placed as close as possible to the device.

### 6.3.16 ADC characteristics

Table 39. ADC characteristics (HSI must be set to PLL mode)

| Symbol                    | Parameter                                | Test conditions                    | Min. | Тур. | Max. | Units |
|---------------------------|------------------------------------------|------------------------------------|------|------|------|-------|
| Ch_diff_num               | Number of channels for differential mode | VFQFPN48, WLCSP49                  | -    | -    | 4    | -     |
| Ch_se_num                 | Number of channels for single ended mode | VFQFPN48, WLCSP49                  | -    | -    | 8    | -     |
| IBAT <sub>ADCBIAS</sub>   | ADC biasing consumption at battery       | Biasing blocks turned on           | -    | 145  | -    | μΑ    |
| IBAT <sub>ADCACTIVE</sub> | ADC active consumption at battery        | ADC activated in differential mode | -    | 185  | -    | μΑ    |
| VDDA                      | Analog supply voltage                    | -                                  | 1.2  | -    | 1.32 | V     |
| R <sub>AIN</sub>          | Input impedance                          | In DC                              | -    | 250  | -    | kΩ    |
| R <sub>in</sub>           | Internal access resistance               | VBOOST is enabled for VDD < 2.7 V  | -    | -    | 550  | Ω     |
| C <sub>in</sub>           | Input sampling capacitor                 | -                                  | -    | 4    | -    | pF    |
| T <sub>s</sub>            | Sampling period                          | Default configuration              | -    | 1    | -    | μs    |

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| Symbol                 | Parameter                          | Test conditions                                                                 |   | Тур. | Max. | Units       |
|------------------------|------------------------------------|---------------------------------------------------------------------------------|---|------|------|-------------|
| T <sub>sw</sub>        | Sampling time                      | Default configuration                                                           |   | 125  | -    | ns          |
| DR                     | Output data rate                   | -                                                                               | - | 200  | -    | k samples/s |
| FRMT <sub>output</sub> | Output data format                 | -                                                                               | - | 16   | -    | bits        |
| TL                     | Latency time                       | 200 kSps                                                                        | - | 5    | -    | μs          |
| T <sub>STARTUP</sub>   | Start-up time                      | From ADC enable to conversion start                                             | - | -    | 1    | μs          |
| DNL                    | Differential non-linearity         | -                                                                               | - | ±0.7 | -    | LSB         |
| INL                    | Integral non-linearity             | -                                                                               | - | ±1   | -    | LSB         |
| SNR Diff               | Signal to noise ratio              | Differential input<br>@1 kHz, -1 dBFs, Fs = 1 MHz with DF                       | - | 72   | -    | dB          |
| STHD Diff              | Signal to THD ratio (10 harmonics) | Differential input<br>@1 kHz, -1 dBFs, Fs = 1 MHz with DF                       | - | 75   | -    | dB          |
| ENOB Diff              | Effective number of bits           | Differential input<br>@1 kHz, -1 dBFs, Fs = 1 MHz with DF                       | - | 11.5 | -    | bits        |
| SNR SE                 | Signal-to-noise ratio              | Single ended<br>@1 kHz, -1 dBFs, Fs = 1 MHz with DF                             | - | 70   | -    | dB          |
| STHD SE                | Signal-to THD ratio (10 harmonics) | Single ended<br>@1 kHz, -1 dBFs, Fs = 1 MHz with DF                             | - | 70   | -    | dB          |
| ENOB SE                | Effective number of bits           | Single ended<br>@1 kHz, -1 dBFs, Fs = 1 MHz with DF                             | - | 11   | -    | bits        |
| -                      | ADC_ERR_1V7                        |                                                                                 | - | 13   | -    |             |
| -                      | ADC_ERR_2V4                        | Absolute error when used for battery measurements at 1.7 V, 2.4 V, 3.0 V, 3.6 V | - | 0    | -    | mV          |
| -                      | ADC_ERR_3V0                        |                                                                                 | - | -9   | -    | IIIV        |
| -                      | ADC_ERR_3V6                        |                                                                                 |   | -22  | -    |             |

# **6.3.17** Temperature sensor characteristics

Table 40. Temperature sensor characteristics

| Symbol              | Parameter                       | Min. | Тур. | Max. | Unit   |
|---------------------|---------------------------------|------|------|------|--------|
| T <sub>rERR</sub>   | Error in temperature            | -    | ±4   | -    | °C     |
| T <sub>SLOPE</sub>  | Average temperature coefficient | -    | 8    | -    | LSB/°C |
| T <sub>ICC</sub>    | Current consumption             | -    | 415  | -    | μA     |
| T <sub>TS-OUT</sub> | Output code at 30 °C (+/-5 °C)  | -    | 2533 | -    | LSB    |

# 6.3.18 Timer characteristics

The characteristics below are guaranteed by design.

**Table 41. TIM1 characteristics** 

| Symbol                | Parameter                   | Test conditions               | Min.     | Тур.   | Max. | Unit |
|-----------------------|-----------------------------|-------------------------------|----------|--------|------|------|
| t <sub>res(TIM)</sub> | Timer resolution time       | f <sub>TIMxCLK</sub> = 64 MHz | -        | 15.625 | -    | ns   |
| R <sub>esTIM</sub>    | Timer resolution            | -                             | -        | 16     | -    | bit  |
| tcounter              | 16-bit counter clock period | f <sub>TIMxCLK</sub> = 64 MHz | 0.015625 | -      | 1024 | μs   |

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| Symbol                 | Parameter                   | Test conditions           | Min. | Тур. | Max.  | Unit |
|------------------------|-----------------------------|---------------------------|------|------|-------|------|
| t <sub>MAX_COUNT</sub> | Maximum possible count time | f <sub>TIMxCLK</sub> = 64 | -    | -    | 67.10 | s    |

Table 42. IWDG min./max. timeout period at 32 kHz (LSE)

| Prescaler divider | PR[2:0] bits | Min. timeout RL[11:0] = 0x000 | Max. timeout RL[11:0] = 0xFFF | Unit |
|-------------------|--------------|-------------------------------|-------------------------------|------|
| /4                | 0            | 0.125                         | 512                           |      |
| /8                | 1            | 0.250                         | 1024                          |      |
| /16               | 2            | 0.500                         | 2048                          |      |
| /32               | 3            | 1.0                           | 4096                          | ms   |
| /64               | 4            | 2.0                           | 8192                          |      |
| /128              | 5            | 4.0                           | 16384                         |      |
| /256              | 6 or 7       | 8.0                           | 32768                         |      |

### 6.3.19 I<sup>2</sup>C interface characteristics

The I<sup>2</sup>C interface meets the timing requirements of the I<sup>2</sup>C-Bus specifications and user manual rev. 03 for:

- Standard-mode (Sm): bit rate up to 100 kbit/s
- Fast-mode (Fm): bit rate up to 400 kbit/s
- Fast-mode plus (Fm+): bit rate up to 1 Mbit/s

SDA and SCL I/O requirements are met with the following restrictions: SDA and SCL I/O pins are not "true" opendrain. When configured as open-drain, the PMOS connected between the I/O pin and VDD is disabled, but is still present. The 20 mA output drive requirement in fast-mode plus is supported partially.

This limits the maximum load C<sub>load</sub> supported in fast-mode plus, given by these formulas:

- $t_r(SDA/SCL) = 0.8473 \times R_p \times C_{load}$
- $R_p(min.) = [V_{DD} V_{OL}(max)] / I_{OL}(max)$

where  $R_p$  is the I<sup>2</sup>C lines pull-up.

All I<sup>2</sup>C SDA and SCL I/Os embed an analog filter.

The characteristics below are guaranteed by design.

Table 43. I<sup>2</sup>C analog filter characteristics

| Symbo | Parameter                                                              | Min. | Max. | Unit |
|-------|------------------------------------------------------------------------|------|------|------|
| tAF   | Maximum pulse width of spikes that are suppressed by the analog filter | 50   | 110  | ns   |

#### 6.3.20 SPI characteristics

The parameters for SPI are derived from tests performed according to  $f_{PCLKx}$  frequency and supply voltage conditions.

- Output speed is set to OSPEEDRy[1:0] = 11
- Capacitive load C = 30 pF
- Measurement points are done at CMOS levels: 0.5 x V<sub>DD</sub>

The characteristics below are specified by design - not tested in production.

Table 44. SPI characteristics

| Symbol           | Parameter           | Conditions Min. |   | Тур. | Max. | Units |
|------------------|---------------------|-----------------|---|------|------|-------|
| f <sub>SCK</sub> | SPI clock frequency | Controller mode | - | -    | 32   | MHz   |

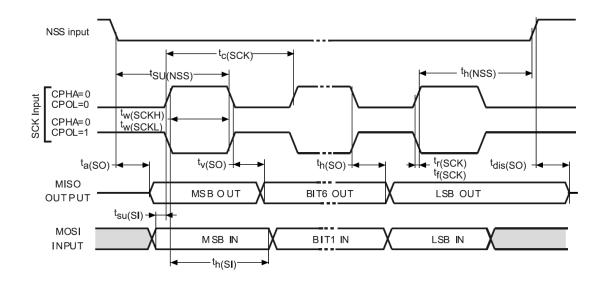
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| Symbol               | Parameter                 | Conditions      | Min.                        | Тур.                  | Max.                     | Units |
|----------------------|---------------------------|-----------------|-----------------------------|-----------------------|--------------------------|-------|
| f <sub>SCK</sub>     | SPI clock frequency       | Target mode     | -                           | -                     | 32 <sup>(1)</sup>        | MHz   |
| tsu(NSS)             | NSS setup time            | -               | 4 / f <sub>PCLK</sub>       | -                     | -                        | -     |
| th(NSS)              | NSS hold time             | -               | 2 / f <sub>PCLK</sub>       | -                     | -                        | -     |
| tw(SCKH)             | COIC high and law times   | Controller made | 1 / f <sub>PCLK</sub> - 1.5 | 1 / f <sub>PCLK</sub> | 1 / f <sub>PCLK</sub> +1 |       |
| tw(SCKL)             | SCK high and low time     | Controller mode | 1 / f <sub>PCLK</sub> - 1.5 | 1 / f <sub>PCLK</sub> | 1 / f <sub>PCLK</sub> +1 |       |
| tsu(MI)              | Data input set-up time    | Controller mode | 1                           | -                     | -                        |       |
| tsu(SI)              | Data input set-up time    | Target mode     | 1                           | -                     | -                        |       |
| th(MI)               | Data input hold time      | Controller mode | 3                           | -                     | -                        |       |
| th(SI)               | Data input hold time      | Target mode     | 1                           | -                     | -                        |       |
| t <sub>a(SO)</sub>   | Data output access time   | Target mode     | 5                           | -                     | 40                       | ns    |
| t <sub>dis(SO)</sub> | Data output disable time  | Target mode     | 5                           | -                     | 38                       |       |
| t <sub>v(MO)</sub>   | Data autout valid time    | Controller mode | -                           | 2                     | 8                        |       |
| t <sub>v(SO)</sub>   | Data output valid time    | Target mode     | -                           | 12                    | 39                       |       |
| t <sub>h(MO)</sub>   | Data as too the old for a | Controller mode | 2                           | -                     |                          |       |
| t <sub>h(SO)</sub>   | Data output hold time     | Target mode     | 4                           | -                     | -                        |       |

The maximum frequency in target transmitter mode is determined by the sum of tv(SO) and tsu(MI), which has to fit SCK low or high phase preceding the SCK sampling edge. This value can be achieved when the SPI communicates with a controller having tsu(MI) = 0 while duty(SCK) = 50 %.

Figure 16. SPI timing diagram - target mode and CPHA = 0



DT57476V1

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Figure 17. SPI timing diagram - target mode and CPHA = 1

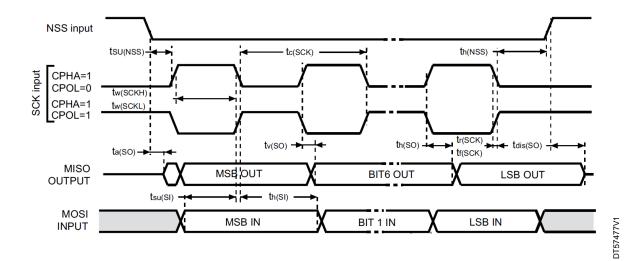
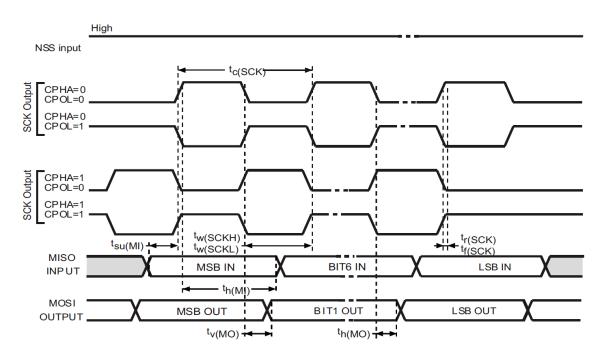


Figure 18. SPI timing diagram - controller mode



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# 7 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

### 7.1 Device marking

Refer to technical note "Reference device marking schematics for STM32 microcontrollers and microprocessors" (TN1433) available on www.st.com, for the location of pin 1 / ball A1 as well as the location and orientation of the marking areas versus pin 1 / ball A1.

Parts marked as "ES", "E" or accompanied by an engineering sample notification letter, are not yet qualified and therefore not approved for use in production. ST is not responsible for any consequences resulting from such use. In no event will ST be liable for the customer using any of these engineering samples in production. ST's Quality department must be contacted prior to any decision to use these engineering samples to run a qualification activity.

A WLCSP simplified marking example (if any) is provided in the corresponding package information subsection.

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# 7.2 VFQFPN32 package information (42)

This VFQFPN is a 32 lead, 5 x 5 mm, 0.50 mm pitch, very fine pitch quad flat no lead package.

SEATING PLANE

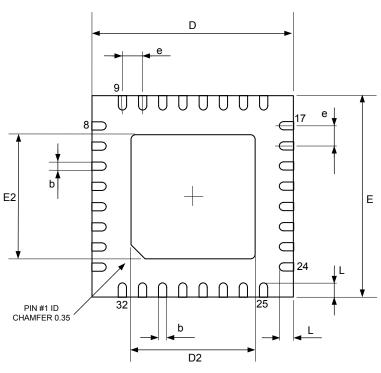
C

B

A3

SIDE VIEW

Figure 19. VFQFPN32 - Outline



42\_VFQFPN32\_CALAMBA\_ME\_V1

- 1. Drawing is not to scale.
- 2. Package outline exclusive of any mold flashes dimensions and metal burrs.
- 3. Details of terminal 1 are optional but must be located on the top surface of the package by using either a mold or marked features.

**BOTTOM VIEW** 

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0.0020

Millimetres Inches(1) **Symbol** Min Тур Max Min Тур Max 0.0315  $A^{(2)}$ 0.80 0.90 1.00 0.0354 0.0394 **A1** 0 0.05 0 0.0020 -А3 0.20 \_ 0.008 \_ \_ b 0.18 0.25 0.30 0.0070 0.0098 0.0118 D 0.2008 4.90 5.00 5.10 0.1929 0.19 Е 5.00 0.1929 0.2008 4.90 5.10 0.19 D2 0.1457 3.60 3.70 3.80 0.1417 0.1496 0.1417 E2 3.70 0.1457 0.1496 3.60 3.80 0.50 \_ 0.0197 \_ \_ е L 0.30 0.40 0.50 0.0118 0.0157 0.0197

Table 45. VFQFPN32 - Mechanical data

1. Values in inches are converted from mm and rounded to 3 decimal digits.

ddd

VFQFPN stands for thermally Enhanced very thin fine pitch quad flat package No lead. Very thin profile 0.80 < A ≤ 1.00 mm.</li>

0.05

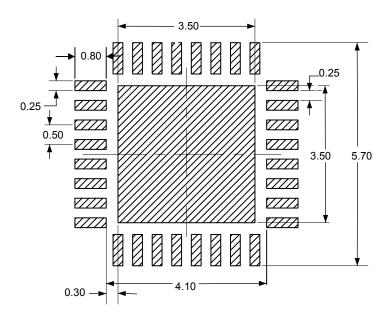


Figure 20. VFQFPN32 - Footprint example

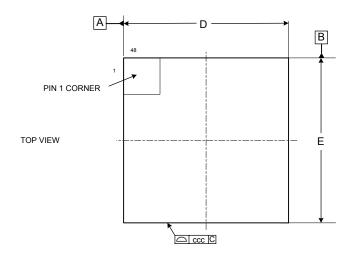
42\_VFQFPN32\_CALAMBA\_FP\_V1

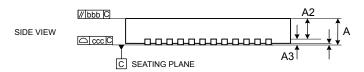


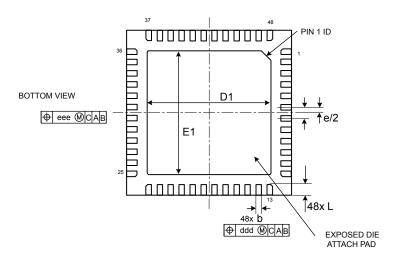
# 7.3 VFQFPN48 package information

This VFQFPN is a 48 lead, 6 x 6 mm, 0.40 mm pitch, very fine pitch quad flat no lead package.

Figure 21. VFQFPN48 - Outline







- 1. Drawing is not to scale.
- 2. Dimension and tolerances conform to ASME Y14.5M.
- 3. Coplanarity applies to leads , corner leads and die attach pad.

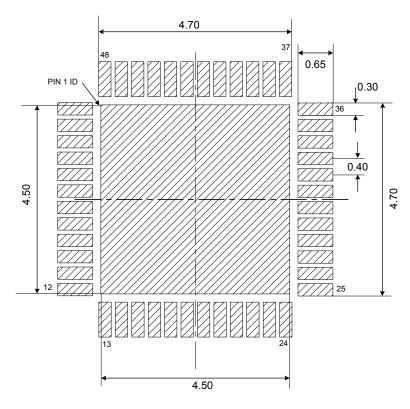
A0BE\_D\_VFQFPN48\_ME\_V1

Table 46. VFQFPN48 - Mechanical data

| Symbol |           | Millimetres |      | Inches <sup>(1)</sup> |            |        |  |
|--------|-----------|-------------|------|-----------------------|------------|--------|--|
| Symbol | Min       | Тур         | Max  | Min                   | Тур        | Max    |  |
| А      | 0.80      | 0.85        | 0.90 | 0.0315                | 0.0335     | 0.0354 |  |
| A1     | 0         | 0.035       | 0.05 | 0                     | 0.0014     | 0.0020 |  |
| A2     | -         | 0.65        | 0.67 | -                     | 0.0256     | 0.0264 |  |
| А3     |           | 0.203 Ref   |      |                       | 0.0080 Ref |        |  |
| b      | 0.15 0.20 |             | 0.25 | 0.006                 | 0.0080     | 0.0098 |  |
| D      |           | 6.00 BSC    |      |                       | 0.2362 BSC |        |  |
| D1     | 4.30      | 4.40        | 4.50 | 0.1693                | 0.1732     | 0.1772 |  |
| E      |           | 6.00 BSC    |      | 0.2362 BSC            |            |        |  |
| E1     | 4.30      | 4.40        | 4.50 | 0.1693                | 0.1732     | 0.1772 |  |
| е      | -         | 0.40 BSC    | -    | -                     | 0.0157 BSC | -      |  |
| L      | 0.40      | 0.45        | 0.50 | 0.0157                | 0.0177     | 0.0197 |  |
| aaa    |           | 0.10        |      |                       | 0.0039     |        |  |
| bbb    | 0.10      |             |      | 0.0039                |            |        |  |
| ccc    | 0.08      |             |      | 0.0031                |            |        |  |
| ddd    |           | 0.10        |      | 0.0039                |            |        |  |

<sup>1.</sup> Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 22. VFQFPN48- Footprint example



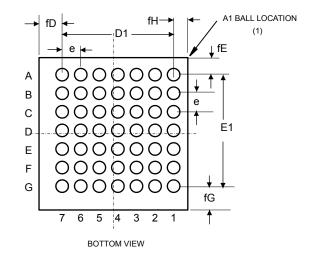
A0BE\_D\_VFQFPN48\_FP\_V1

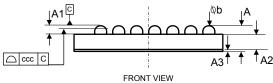


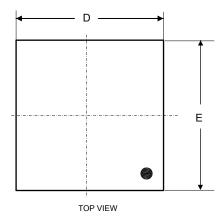
# 7.4 WLCSP49 package information( 01C1)

This WLCSP is a 49-ball, 3.140 x 3.140 mm, 0.40 mm pitch, wafer level chip scale array package.

Figure 23. WLCSP49 - Outline







- 01C1\_WLCSP49\_ME\_V1
- The terminal A1 on the bumps side is identified by a distinguishing feature (for instance by a circular "clear area" - typically 0.1 mm diameter) and/or a missing bump.
   The terminal A1 on the backside of the product is identified by a distinguishing feature (for instance by a circular "clear area" - typically 0.5 mm diameter).
- 2. Drawing is not to scale.

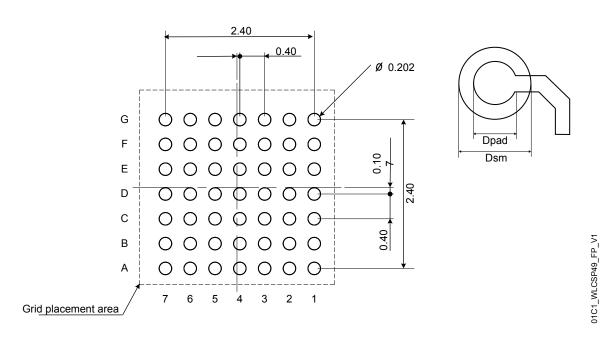


Table 47, WLCSP49 - Mechanical data

| Symbol |       | millimeters |       |        | inches <sup>(1)</sup> |        |
|--------|-------|-------------|-------|--------|-----------------------|--------|
| Symbol | Min   | Тур         | Max   | Min    | Тур                   | Max    |
| А      | -     | -           | 0.420 | -      | -                     | 0.0165 |
| A1     | 0.135 | -           | -     | 0.0053 | -                     | -      |
| A2     | -     | 0.225       | -     | -      | 0.0088                | -      |
| A3     | -     | 0.025       | -     | -      | 0.0010                | -      |
| b      | 0.214 | 0.218       | 0.222 | 0.0084 | 0.0085                | 0.0087 |
| D      | -     | 3.140       | -     | -      | 0.1236                | -      |
| D1     | -     | 2.400       | -     | -      | 0.0945                | -      |
| E      | -     | 3.140       | -     | -      | 0.1236                | -      |
| E1     | -     | 2.400       | -     | -      | 0.0945                | -      |
| е      | -     | 0.40        | -     | -      | 0.0157                | -      |
| fD     | -     | 0.416       | -     | -      | 0.0164                | -      |
| fE     | -     | 0.263       | -     | -      | 0.0103                | -      |
| fG     | -     | 0.477       | -     | -      | 0.0188                | -      |
| fH     | -     | 0.324       | -     | -      | 0.0127                | -      |
| aaa    | -     | 0.023       | -     | -      | 0.0009                | -      |

<sup>1.</sup> Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 24. WLCSP49 - Footprint example



1. Dimensions are expressed in millimeters.

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Table 48. WLCSP49 - Example of PCB design rules

| Dimension         | Values                                                       |
|-------------------|--------------------------------------------------------------|
| Pitch 0.4 mm      |                                                              |
| Dpad              | 0,225 mm                                                     |
| Dsm               | 0.290 mm typ. (depends on soldermask registration tolerance) |
| Stencil opening   | 0.250 mm                                                     |
| Stencil thickness | 0.100 mm                                                     |

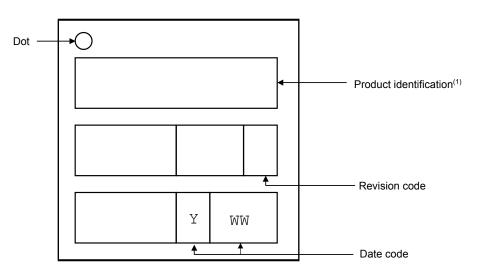
### 7.4.1 Device marking for WLCSP49

The following figure gives an example of topside marking versus ball A1 position identifier location.

The printed markings may differ depending on the supply chain.

Other optional marking or inset/upset marks, which depend on supply chain operations, are not indicated below.

Figure 25. WLCSP49 marking example



Parts marked as "ES", "E" or accompanied by an Engineering Sample notification letter, are not yet qualified
and therefore not approved for use in production. ST is not responsible for any consequences resulting from
such use. In no event will ST be liable for the customer using any of these engineering samples in production.
ST's Quality department must be contacted prior to any decision to use these engineering samples to run a
qualification activity.

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#### 7.5 Thermal characteristics

The maximum chip junction temperature ( $T_{Jmax.}$ ) must never exceed the values in general operating conditions. The maximum chip-junction temperature,  $T_{J}$  max., in degrees Celsius, can be calculated using the equation:

$$T_I \max . = T_A \max . + (PD \max \times \theta JA) \tag{1}$$

where:

- T<sub>A</sub> max. is the maximum ambient temperature in °C
- OJA is the package junction-to-ambient thermal resistance, in °C/W
- PD max. is the sum of PINT max. and PI/O max. (PD max. = PINT max. + PI/O max.)
- PINT max. is the product of IDD and VDD, expressed in Watt. This is the maximum chip internal power PI/O max represents the maximum power dissipation on output pins:
- PI/O max. =  $\Sigma$  (VOL × IOL) +  $\Sigma$  ((VDD VOH) × IOH)

taking into account the actual VOL / IOL and VOH / IOH of the I/Os at low and high level in the applications.

Note: When the SMPS is used, a portion of the power consumption is dissipated into the external inductor, therefore reducing the chip power dissipation. This portion depends mainly on the inductor ESR characteristics.

Note: As the radiated RF power is quite low (< 4 mW), it is not necessary to remove it from the chip power consumption.

Note: RF characteristics (such as: sensitivity, Tx power, consumption) are provided up to 85 °C.

 Symbol
 Parameter
 Value
 Unit

 Thermal resistance junction-ambient<br/>VFQFPN48 – 6 mm x 6 mm
 25.1

 Thermal resistance junction-ambient<br/>VFQFPN32 - 5 mm x 5 mm
 26.9
 °C/W

 Thermal resistance junction-ambient<br/>WLCSP49 – 0.4 mm pitch

Table 49. Package thermal characteristics

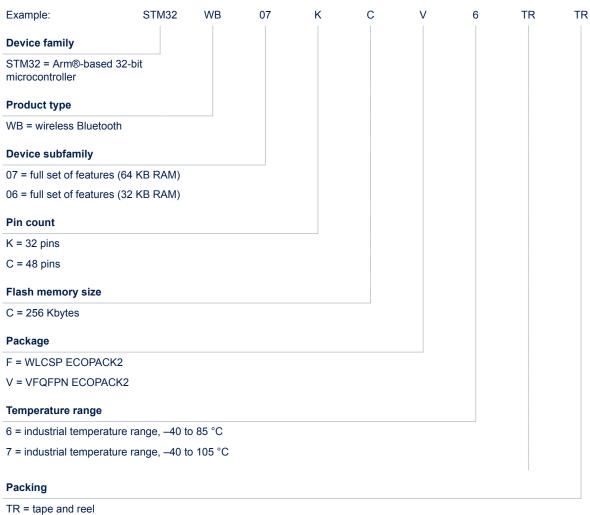
# 7.5.1 Reference documents

- JESD51-2 Integrated Circuits Thermal Test Method Environment Conditions Natural Convection (Still Air) available on www.jedec.org.
- For information on thermal management, refer to application note "Guidelines for thermal management on STM32 applications" (AN5036) available on www.st.com.

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# 8 Ordering information



TR = tape and ree

Note:

For a list of available options (such as speed and package) or for further information on any aspect of this device, contact your nearest ST sales office.

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# **Revision history**

Table 50. Document revision history

| Date        | Revision | Changes                                                                                                                  |  |
|-------------|----------|--------------------------------------------------------------------------------------------------------------------------|--|
| 13-Jun-2024 | 1        | Initial release.                                                                                                         |  |
| 04-Sep-2024 | 2        | Updated VFQFPN32 package information                                                                                     |  |
| 26-Sep-2024 | 3        | Updated:  Table 6. STM32WB0xxC pin/ball definition Table 7. Alternate function port A Table 8. Alternate function port B |  |
| 13-Feb-2025 | 4        | Updated Table 5. Legend/abbreviations used in the pinout table                                                           |  |
| 21-Mar-2025 | 5        | Updated:  Features  All occurrences of Bluetooth Low Energy to Bluetooth® LE.                                            |  |

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